

Photocathode Physics: Band Structure and Emittance

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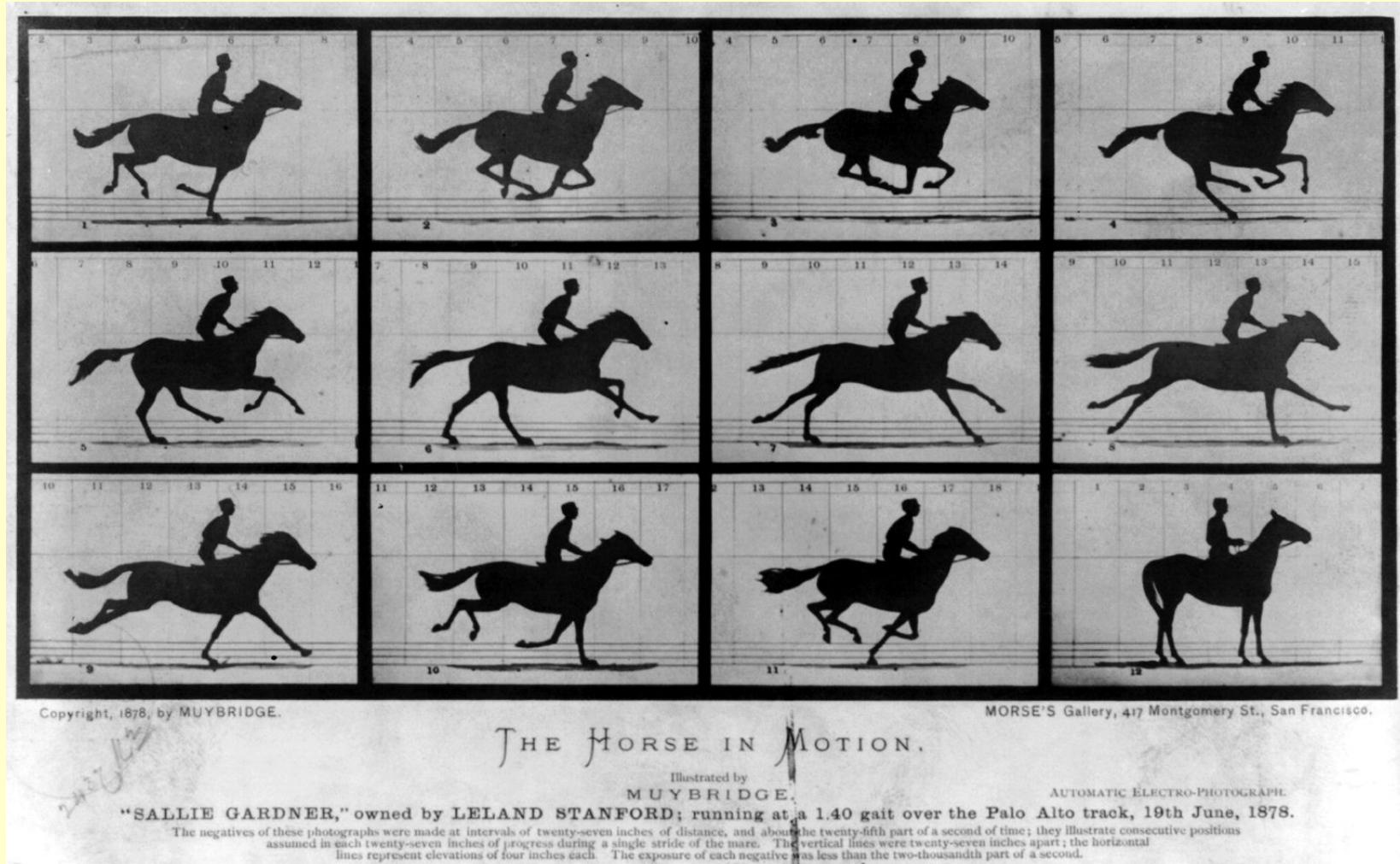
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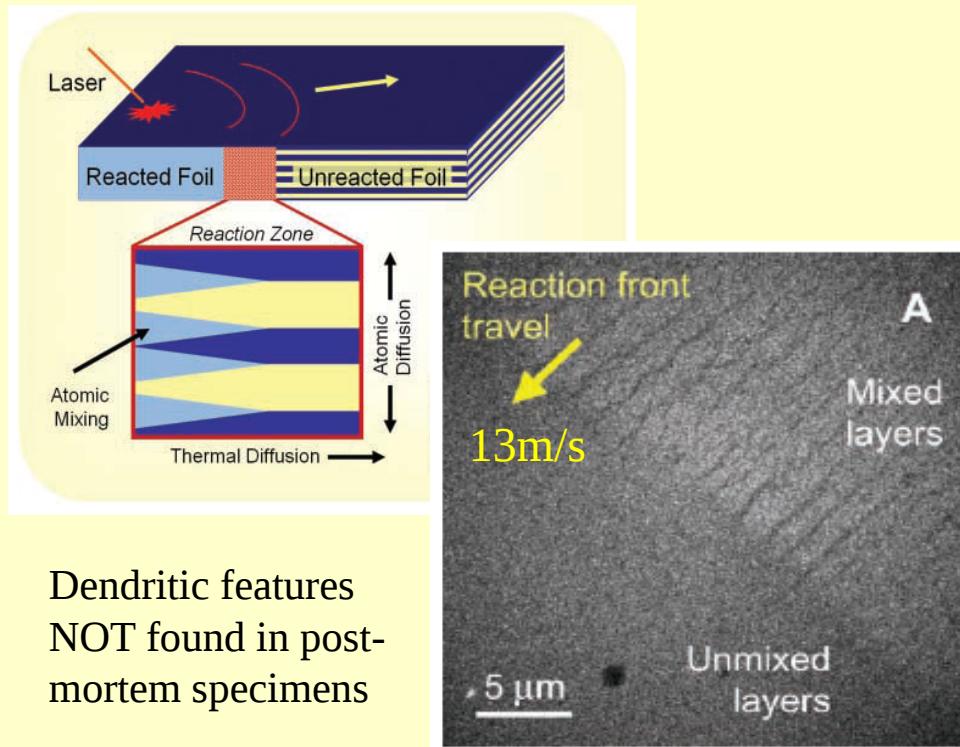
Space-time resolution



E. Muybridge (photographer, 1878): $\delta t = 0.002\text{s}$ and $\delta x \sim 10\text{cm}$
 \Rightarrow Space-time resolution, $\delta x \cdot \delta t \sim 1 \text{ mm} \cdot \text{second}$

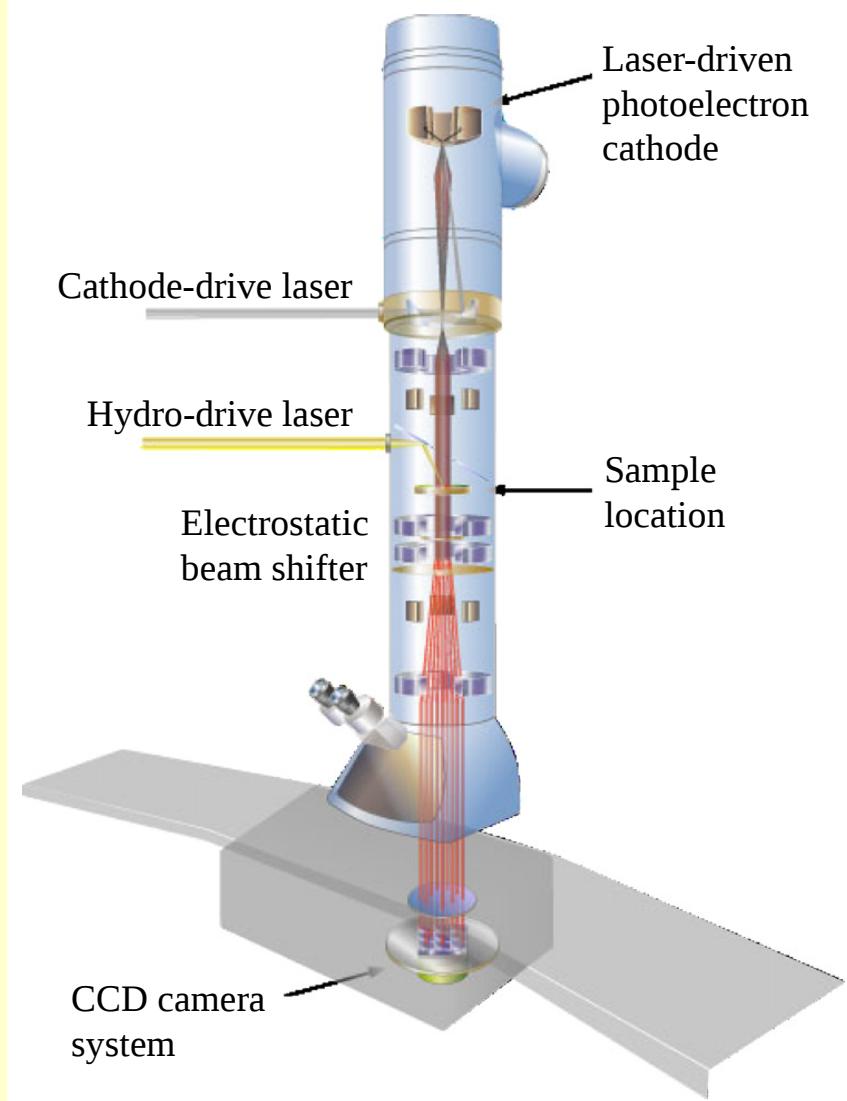
Dynamic TEM

- LLNL DTEM: Single-shot *imaging*
- Laser-initiated reaction in Al/Ni reactive multi-layer foil (RMLF):



Dendritic features
NOT found in post-
mortem specimens

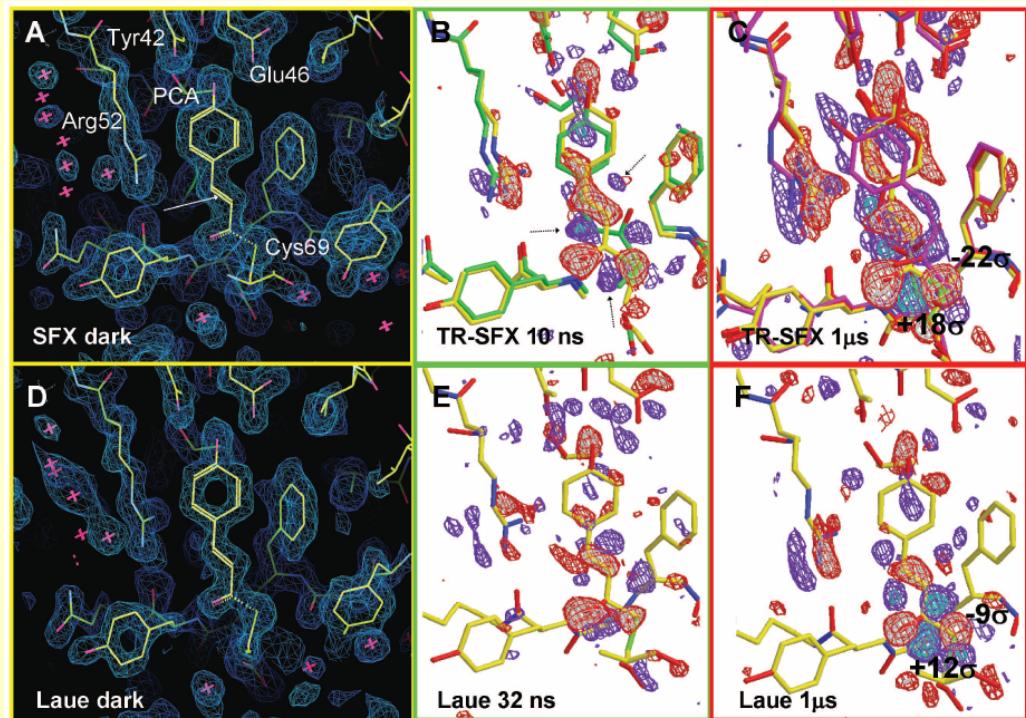
$$\delta x \cdot \delta t \approx 10\text{nm} \cdot 10\text{ns} \sim 100 \text{ nm} \cdot \text{ns}$$



Ultrafast X-ray diffraction

– SLAC X-ray free electron laser (XFEL)

- Reaction intermediates of photoactive yellow protein:



$$\delta x \cdot \delta t \approx 1.6 \text{ Å} \cdot 100 \text{ ps} > 10^{-2} \text{ nm.ns}$$



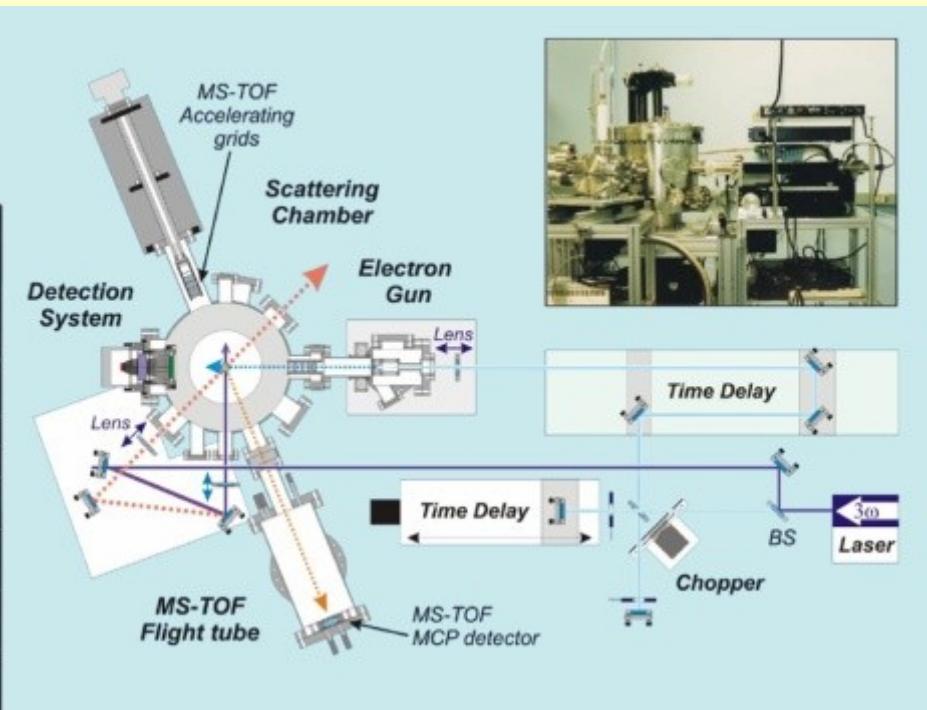
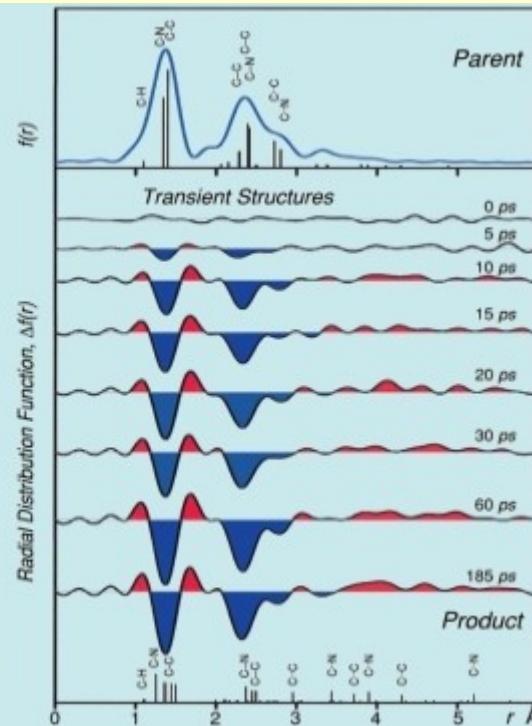
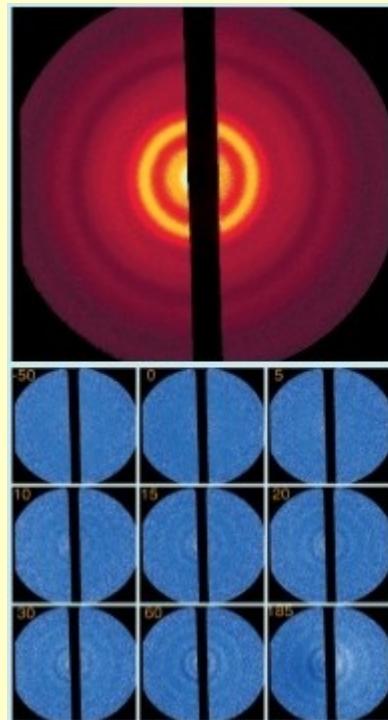
Ultrafast electron diffraction (UED)

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- A. Zewail: 1999 Nobel Prize in Chemistry

- ## ■ Pump-probe technique:

- Laser pulse initiates perturbation
 - Time-delayed electron pulse monitors changes

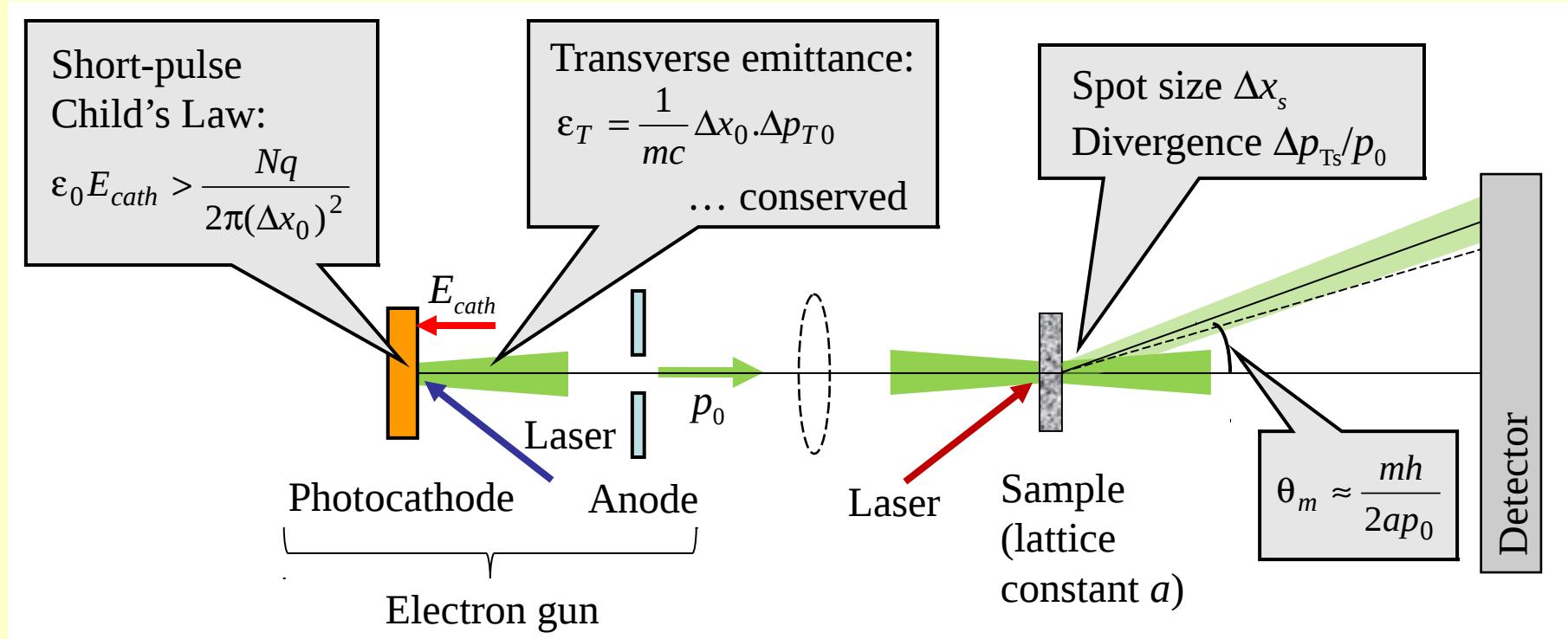


Modern *single-shot* UED systems:
 $\delta x \cdot \delta t < 1\text{\AA}.100\text{fs} = 10^{-5} \text{ nm.ns}$

UED: Spatial Resolution Limit

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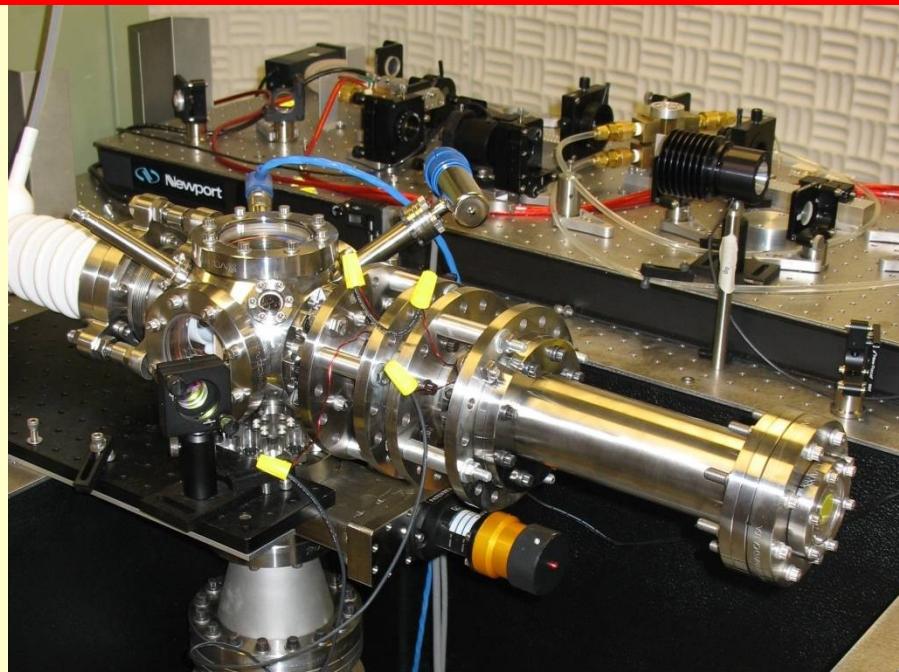
- Non-relativistic regime



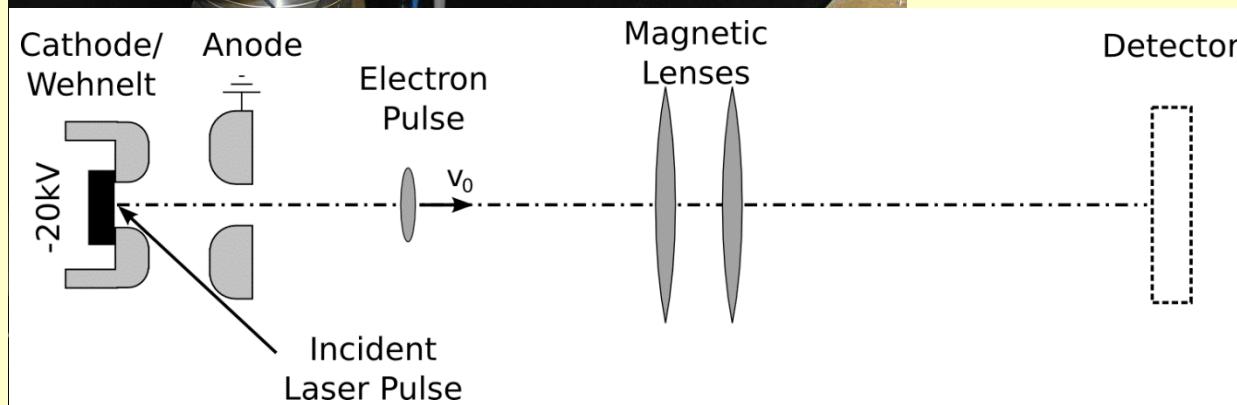
$$\Rightarrow \text{Observable } \frac{\delta a}{a} \geq \frac{\xi}{mh} \left(\frac{a}{\Delta x_s} \right) \sqrt{\frac{2Nq}{\pi \varepsilon_0 E_{cath}}} \cdot \Delta p_{T0} ; \text{ with } \Delta p_{T0} = ??$$

Δp_{T0} Measurement: Solenoid Scan

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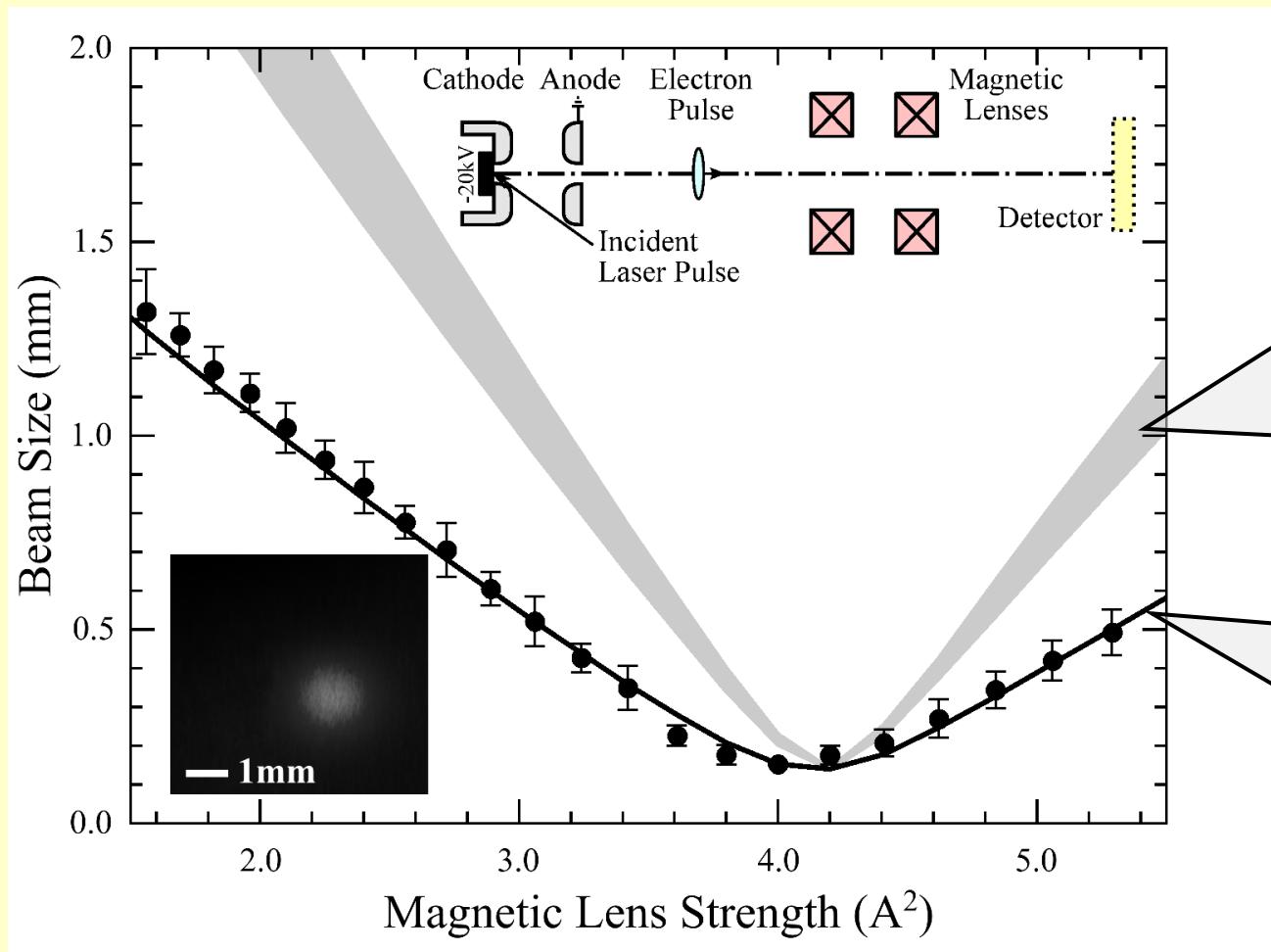


- 2W, 250fs, 63MHz , diode-pumped Yb:KGW laser
 - $\sim 4\text{ps}$ at 261nm ($\hbar\omega = 4.75\text{eV}$)
- YAG scintillator optically coupled to CCD camera
 - Beam size vs. magnetic coil (lens) current measured
 - Analytical Gaussian (AG) pulse propagation model to extract Δp_{T0}



Results: Polycrystalline Cr

- Solenoid scan measurement



Range for Δp_T from

$$\Delta p_{T0} = \sqrt{\frac{m_0(\hbar\omega - \phi)}{3}}$$

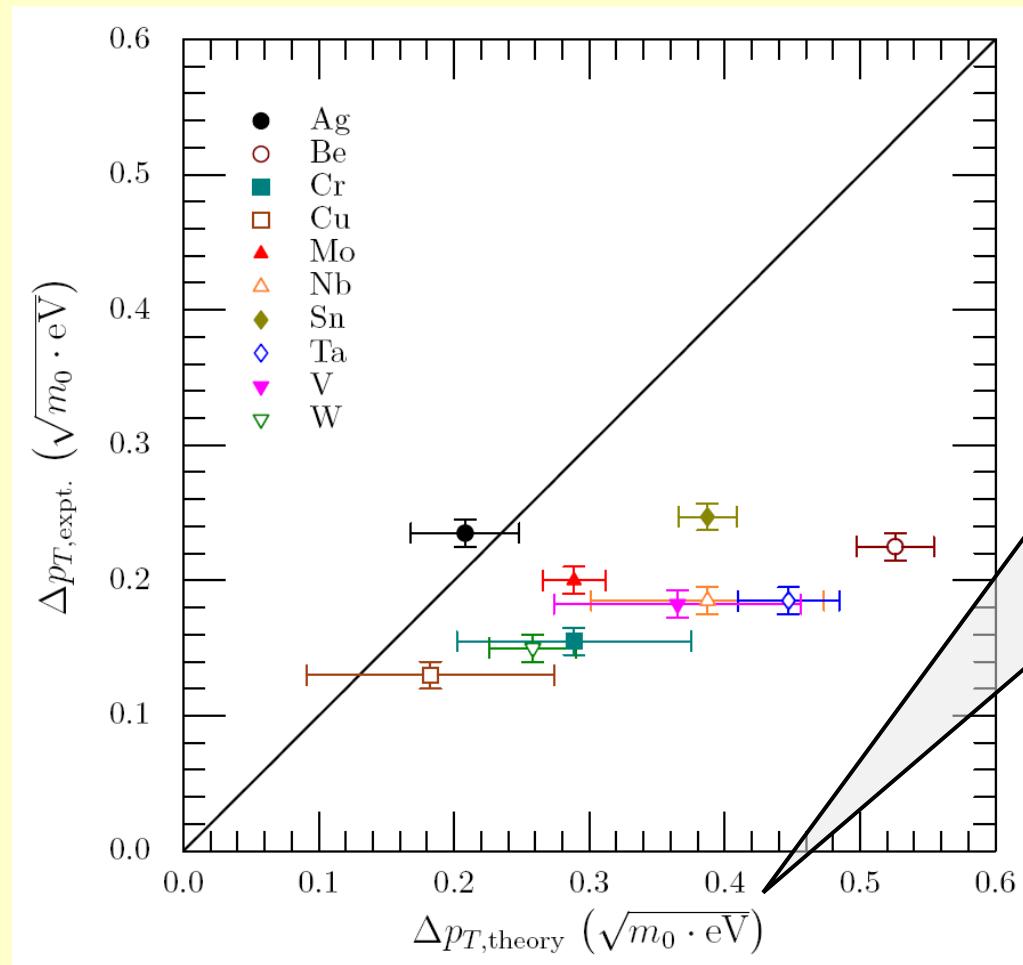
... $\phi = 4.50(\pm 0.05)\text{eV}$
and $\hbar\omega = 4.75\text{eV}$

AG model simulation
of experiment gives

$$\Delta p_{T0} = 0.155(\pm 0.01) \quad (\text{m}_0 \cdot \text{eV})^{1/2}$$

Results: 10 Polycrystalline Metals

– Δp_T from solenoid scan measurements vs. standard theory



Standard expression,

$$\Delta p_{T0} = \sqrt{\frac{m_0(\hbar\omega - \phi)}{3}},$$

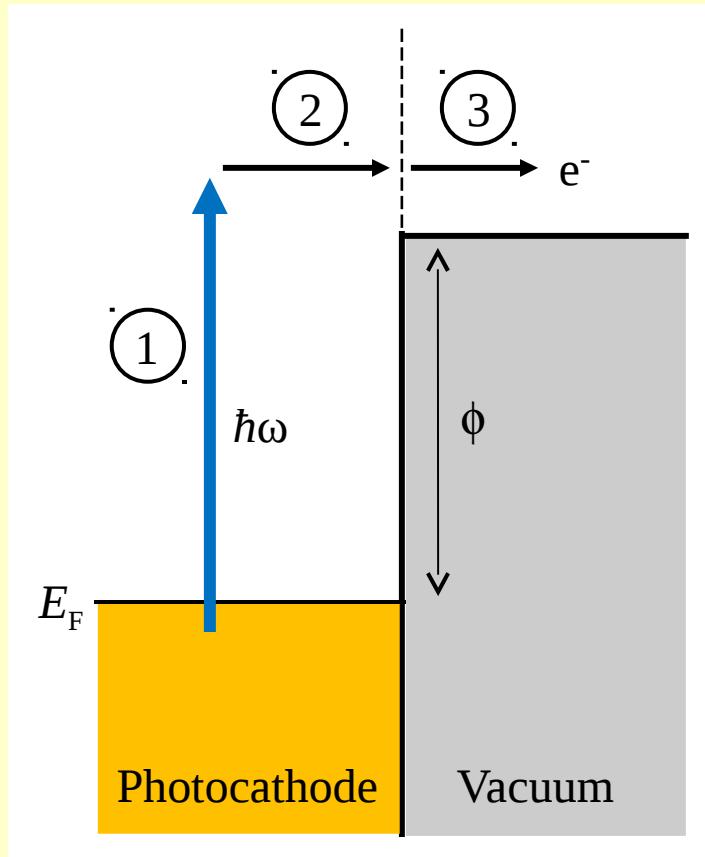
assumes:

- (i) Isotropic parabolic electron-like bands;
- (ii) Constant density of states;
- (iii) $m^* = m_0$, the free electron mass.

Disagreement \Rightarrow Band structure effect ?

Photoemission Theory I

- The semi-classical three-step ‘Spicer’ model



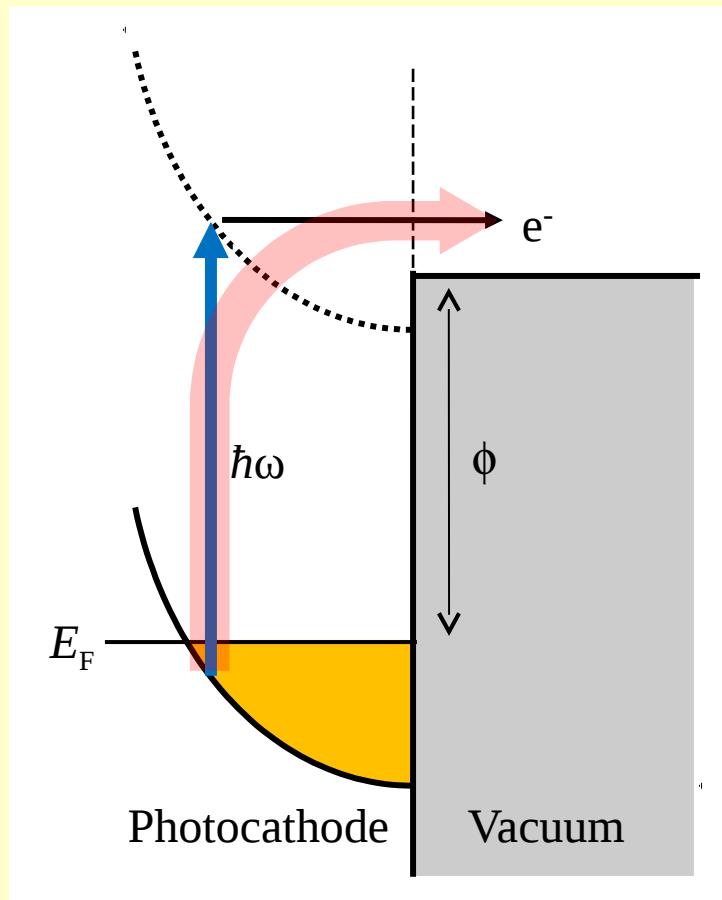
1. Photoexcitation
 2. Transport to surface
 3. Emission from surface
- Transport \Rightarrow ***Real*** electronic band
 \therefore Photoexcitation into upper state near vacuum level
 - Emission from upper excited state \Rightarrow High quantum efficiency (η_{PE})
AND
 Response time \approx Lifetime (ps-ns)

\therefore **NOT** suitable for UED

Examples: NEA GaAs, KCsSb, GaSb,
diamond, Cu(111)?

Photoemission Theory II

- The ‘quantum mechanical’ one-step model



Photoexcitation into a **virtual** state
(excited copy of filled band)
emitting into the vacuum in one step

- Low $\eta_{PE} \sim 10^{-5}$ to 10^{-7}
- ‘Instantaneous’ emission process

Suitable for UED

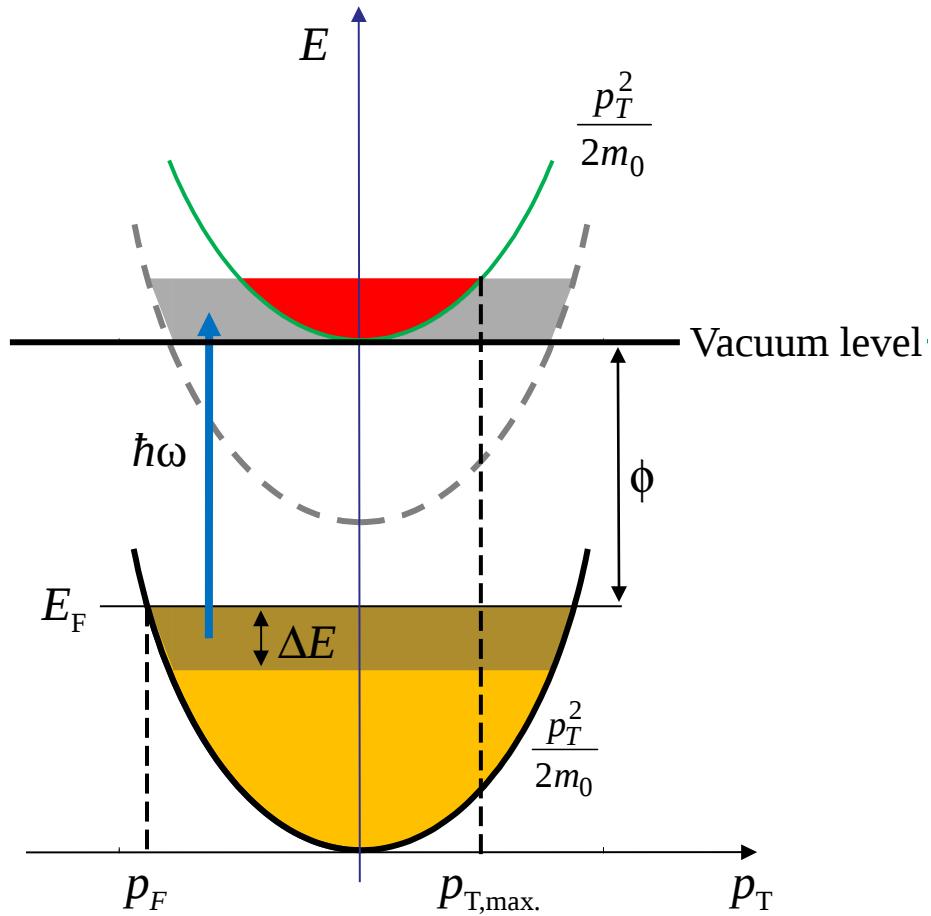
Examples: Most metals

Band Structure Effects

- Transverse momentum p_T conserved in photoemission

‘Classical’ metal

$$m^* = m_0$$



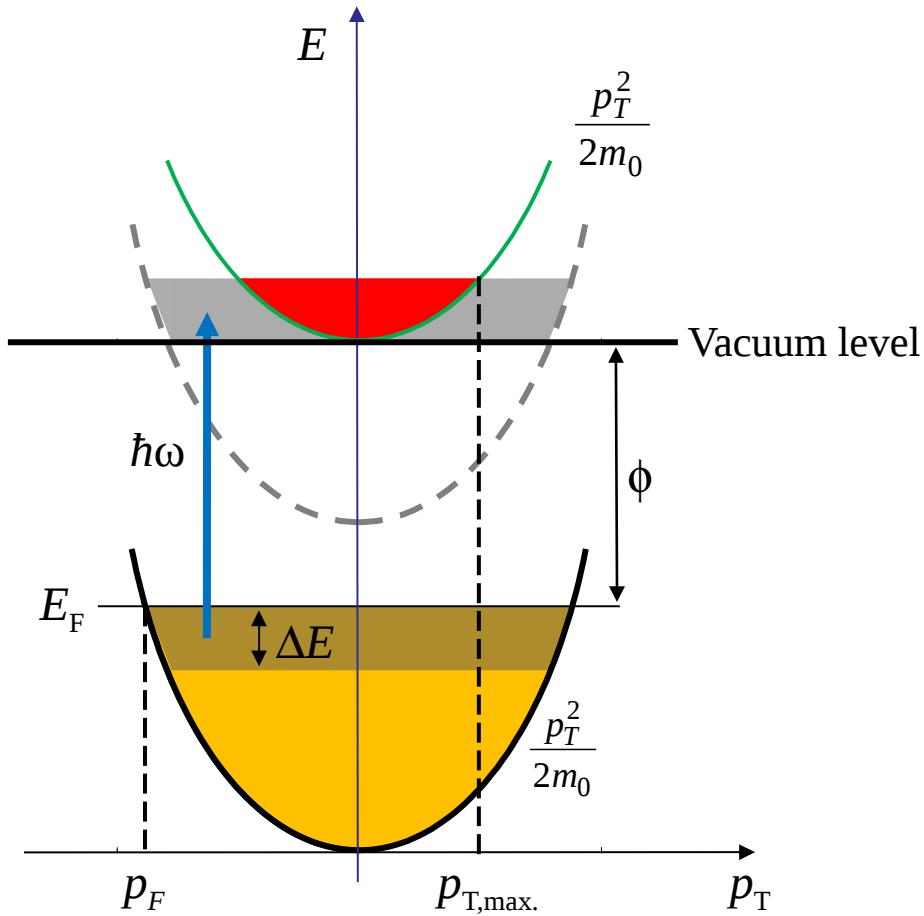
Band Structure Effects

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- Transverse momentum p_T conserved in photoemission

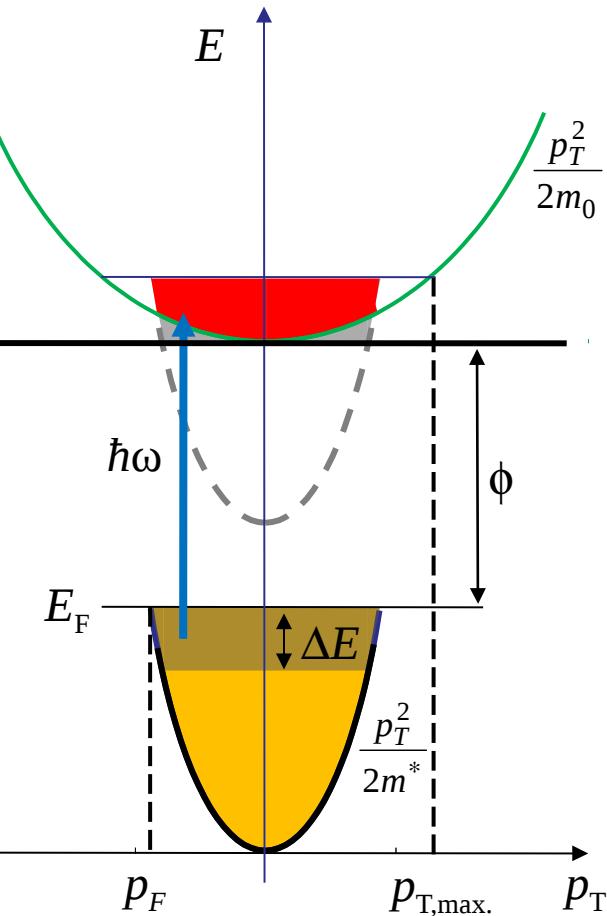
‘Classical’ metal

$$m^* = m_0$$



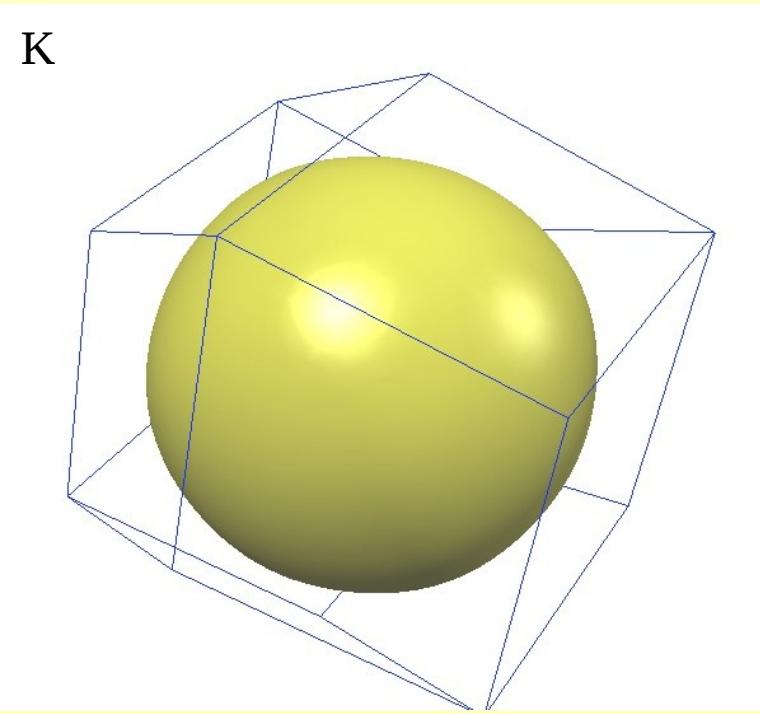
Metal with $m^* < m_0$

$$p_{T,\max.} = \sqrt{2m_0\Delta E} > p_F = \sqrt{2m^* E_F}$$



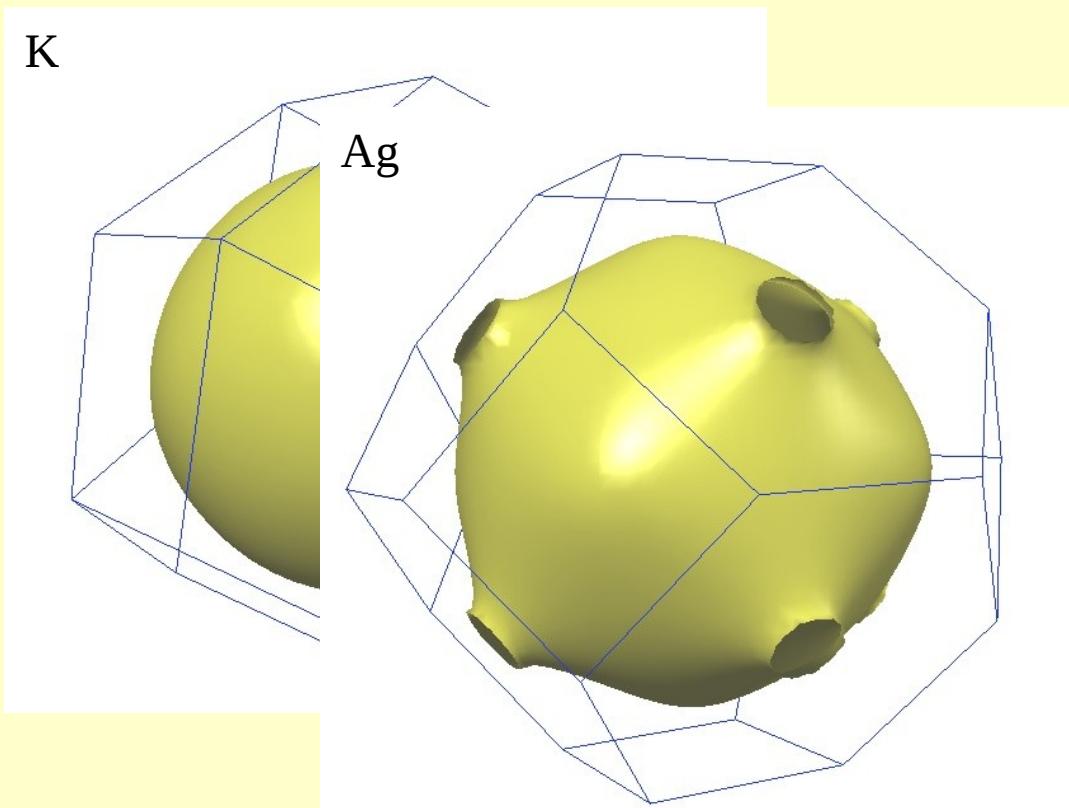
Fermi Surfaces

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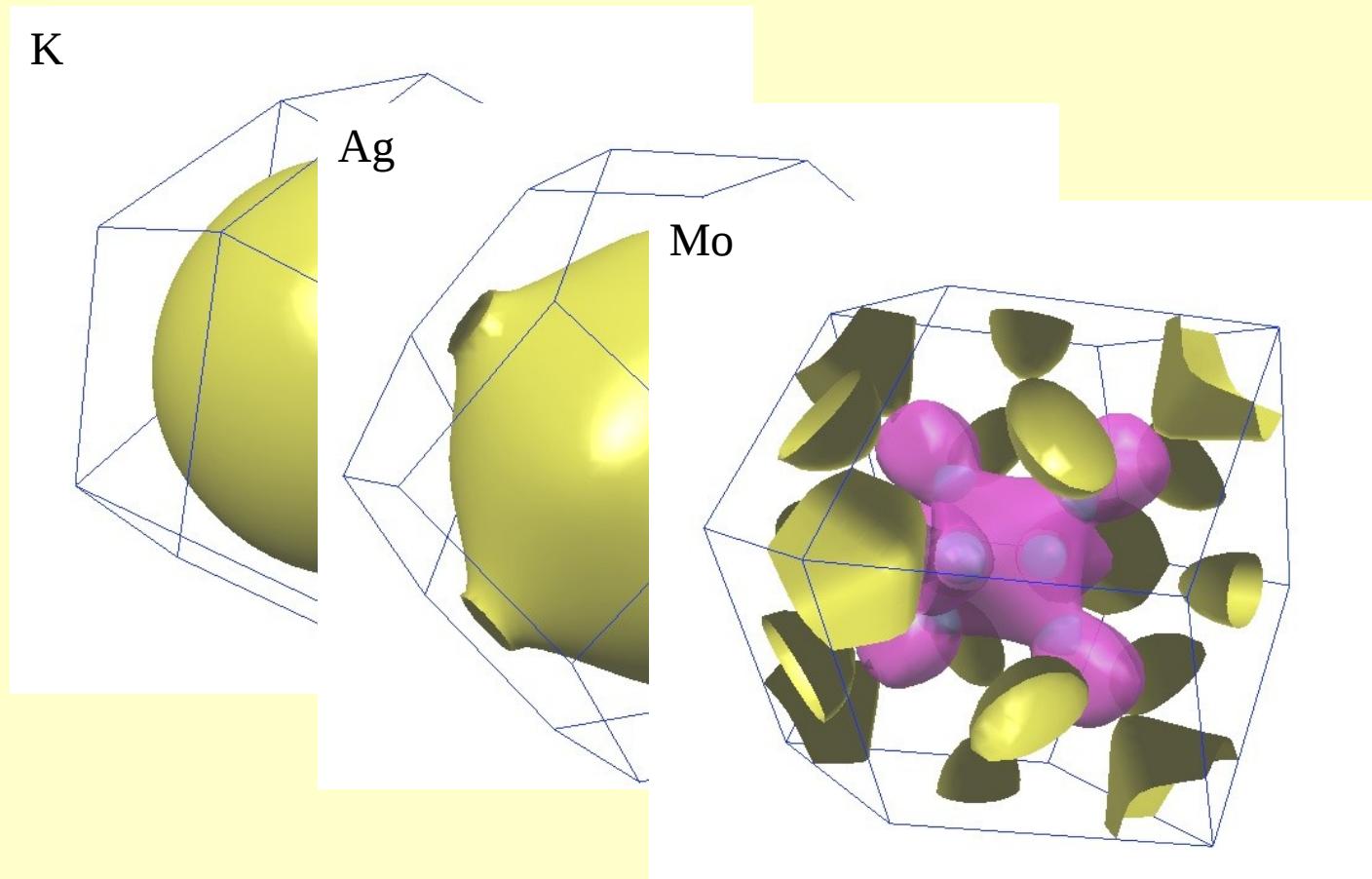
Fermi Surfaces

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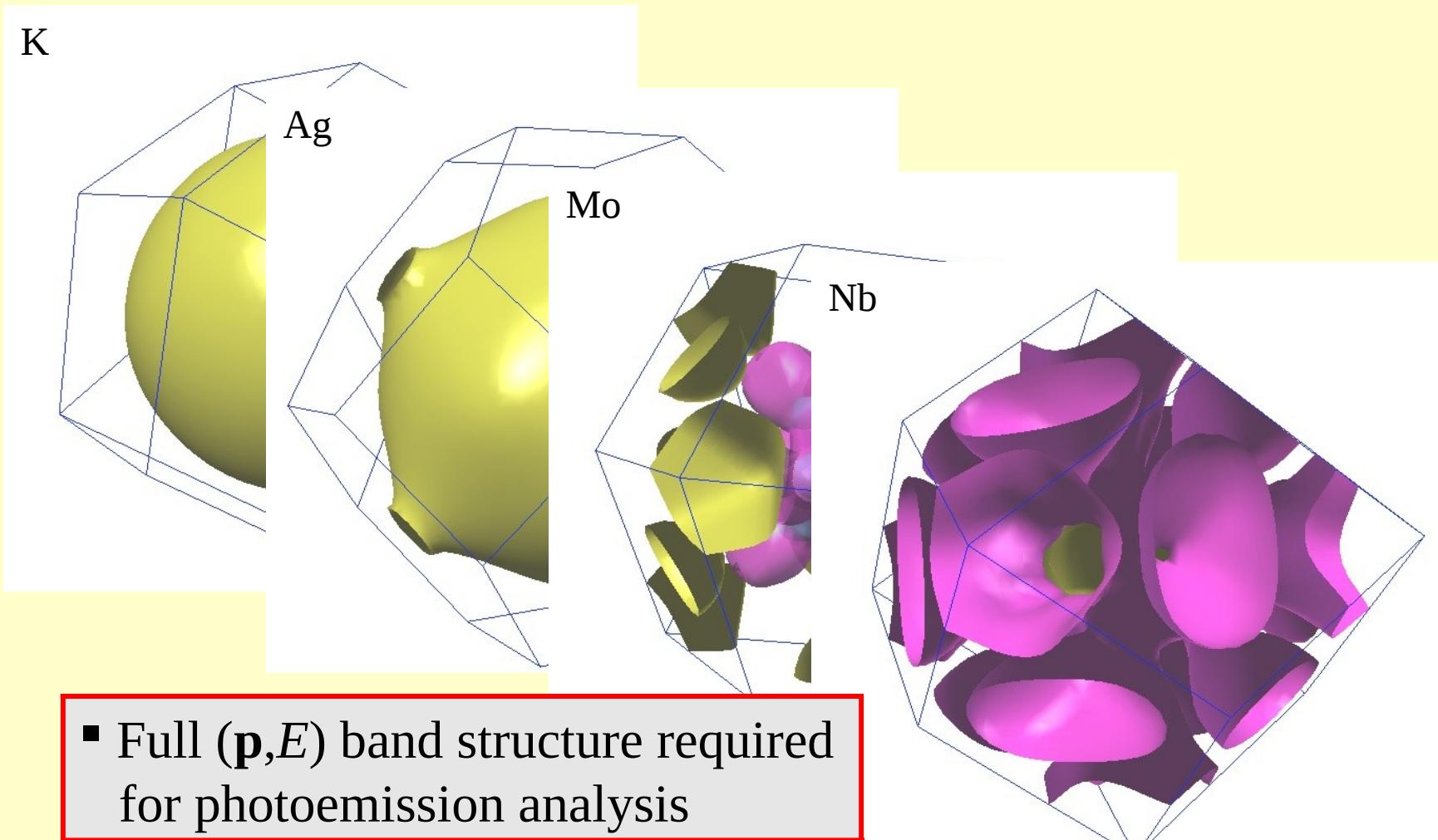
Fermi Surfaces

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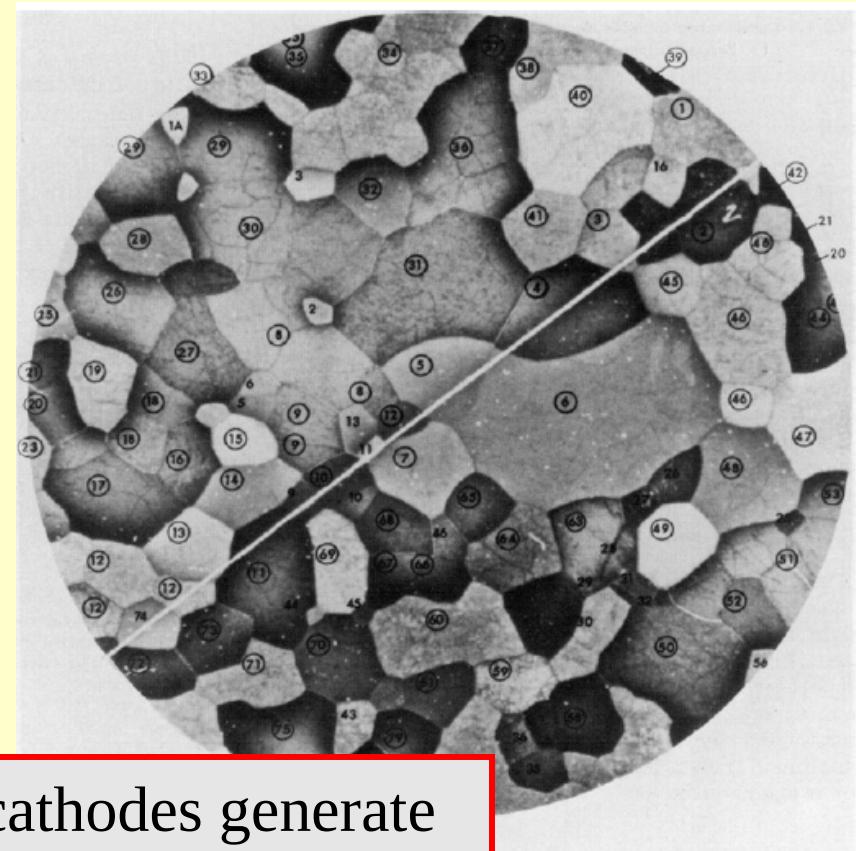
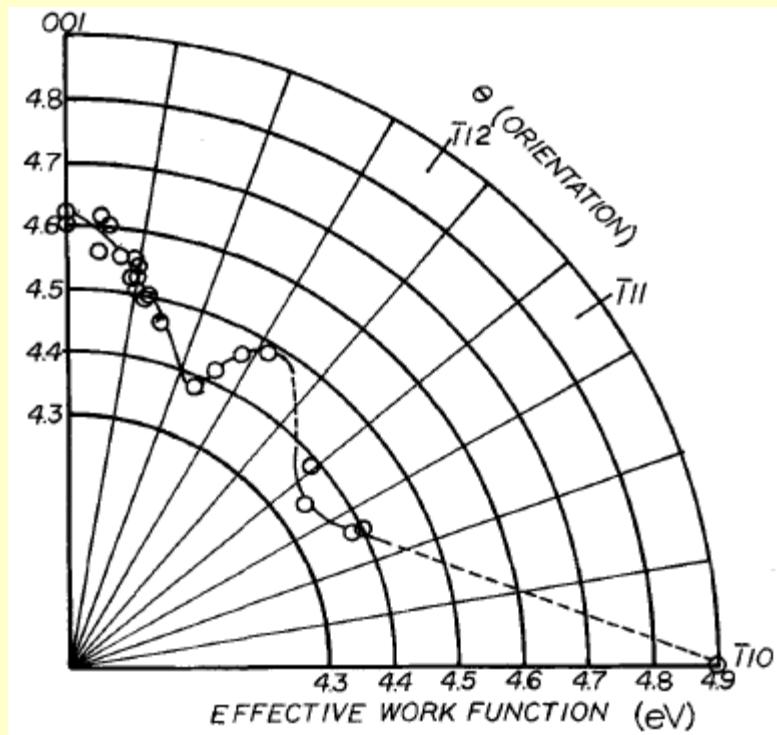
Fermi Surfaces

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Work Function Anisotropy

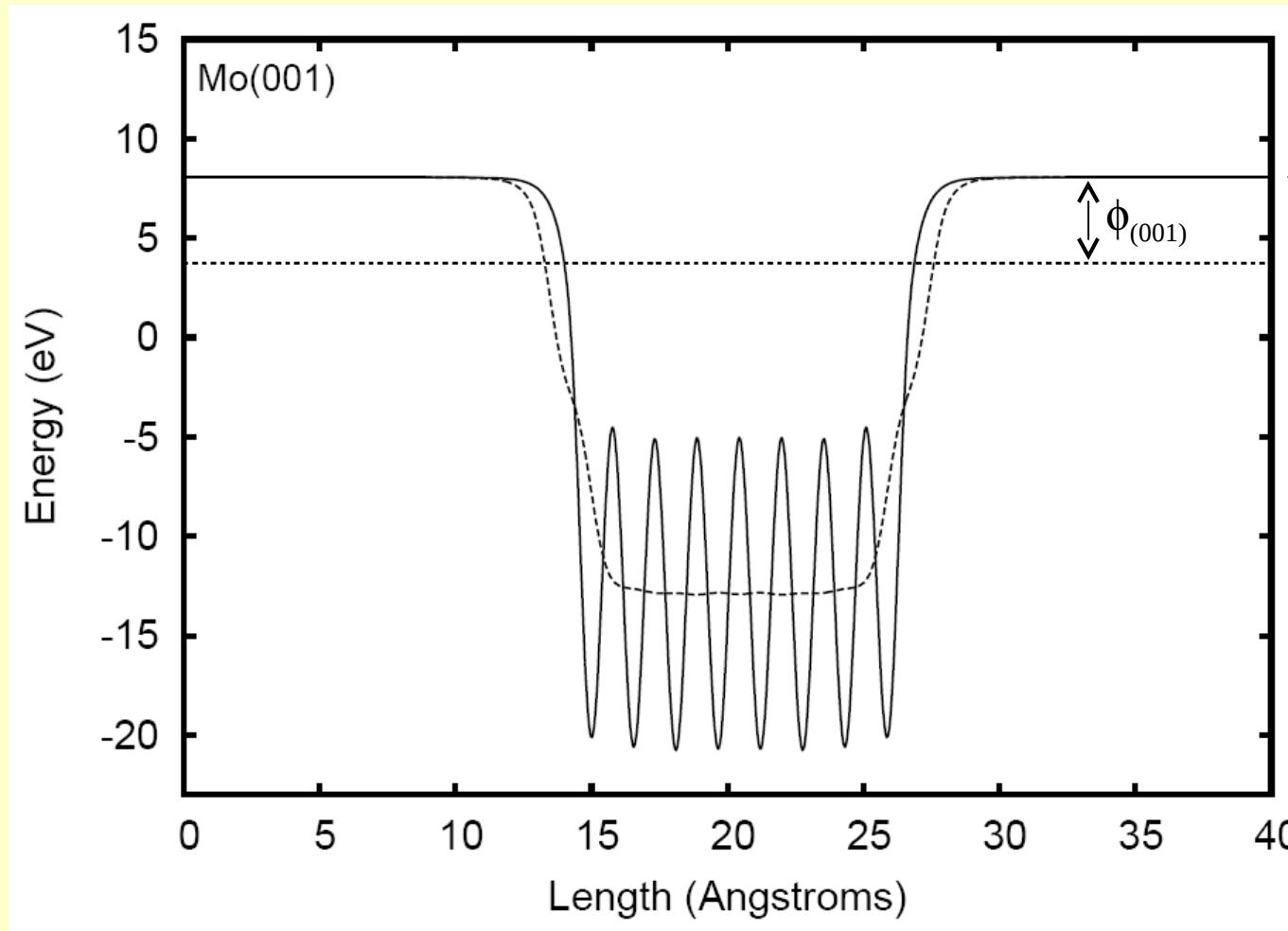
- Example: $\phi_{(ijk)}$ for Mo by electron emission microscopy



- Polycrystalline metal photocathodes generate *inhomogeneous* electron beams
- Any photoemission analysis **must** include $\phi_{(ijk)}$

Thin-slab Evaluation of $\phi_{(ijk)}$

- Example: $\phi_{(001)} = 4.53(\pm 0.05)\text{eV}$ for Mo



NOTE

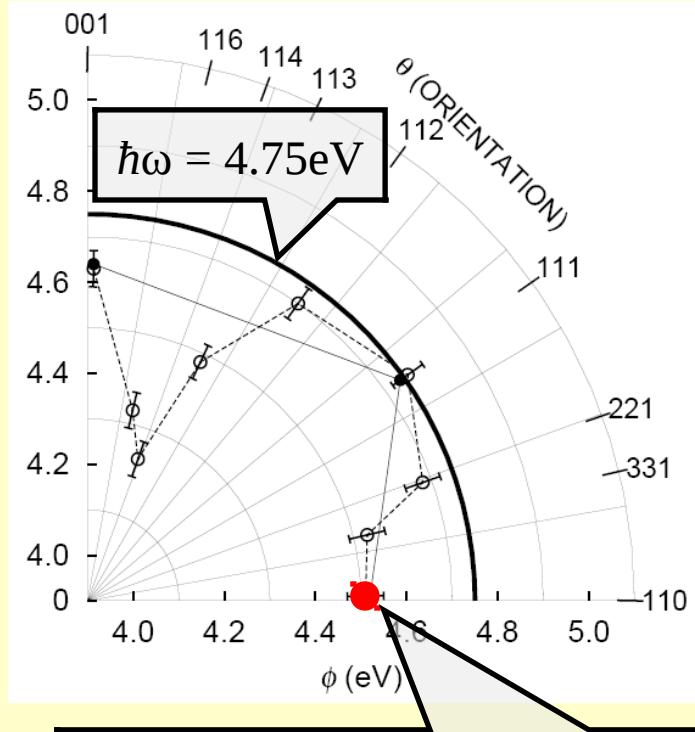
Schottky effect *not* included:

$$\frac{e}{2} \sqrt{\frac{eE_{DC}}{\pi\epsilon_0}} \approx \pm 50\text{meV}$$

uncertainty in $\phi_{(ijk)}$

Photoemission Simulation: Ag

– fcc crystal lattice



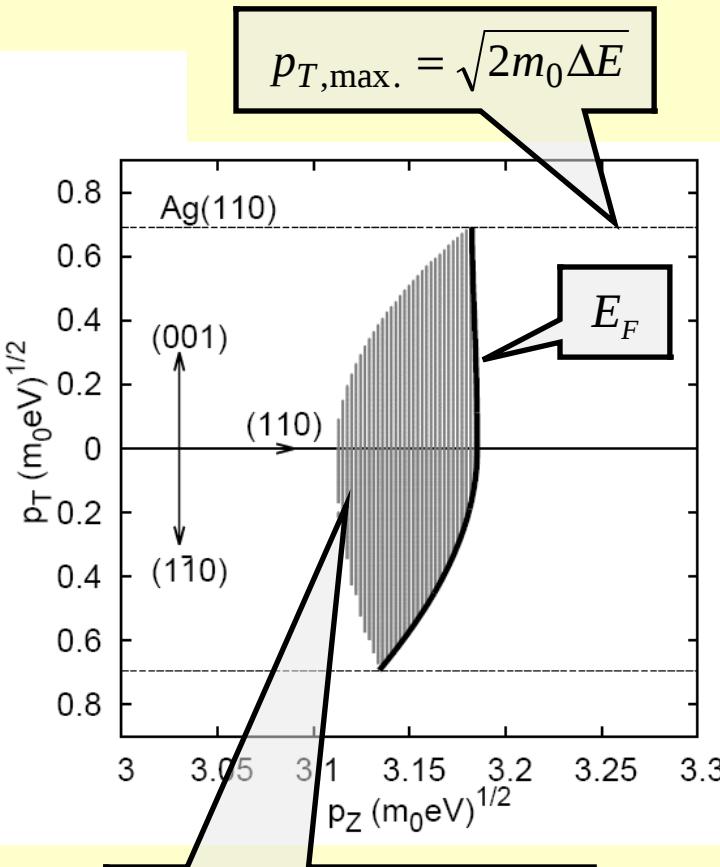
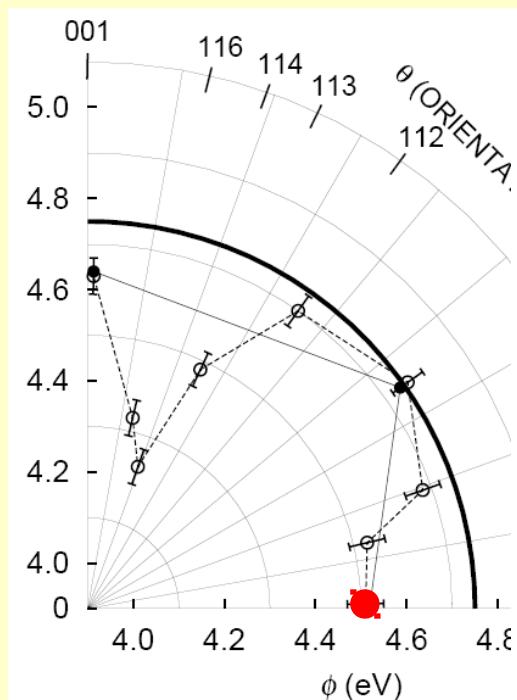
Lowest index face
with lowest $\phi_{(ijk)}$

$$\Delta E = \hbar\omega - \phi_{(110)} = 0.23\text{eV}$$

... $\pm 50\text{meV}$ error in $\phi_{(ijk)}$

Photoemission Simulation: Ag

– fcc crystal lattice

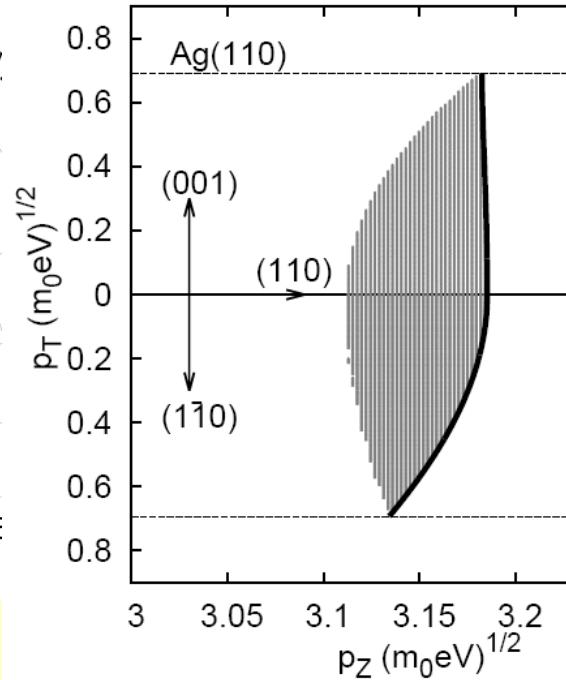
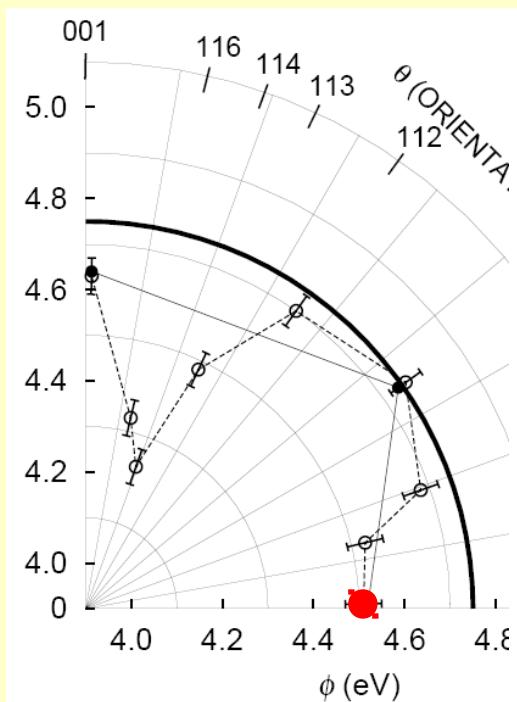


Photoemitting
electron-like states for
 $\hbar\omega = 4.75 \text{ eV}$
(\mathbf{p}_T and E conserved)

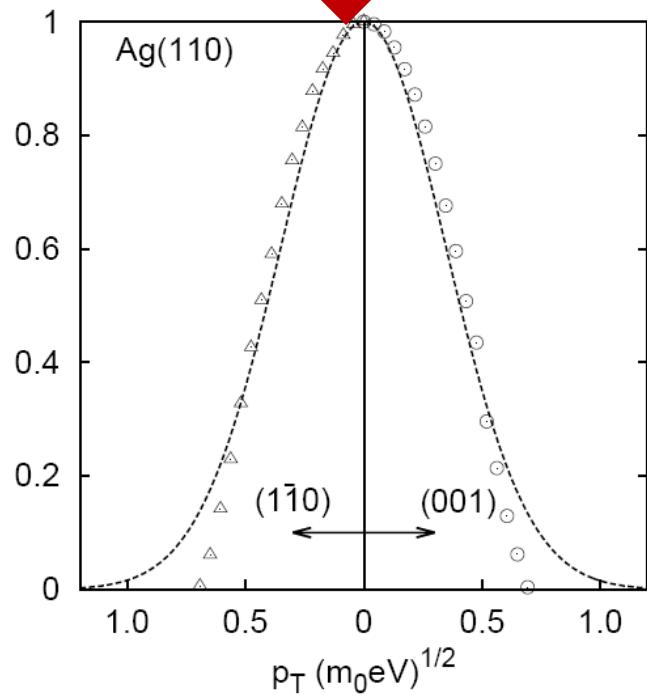
Photoemission Simulation: Ag

UIC

- fcc crystal lattice



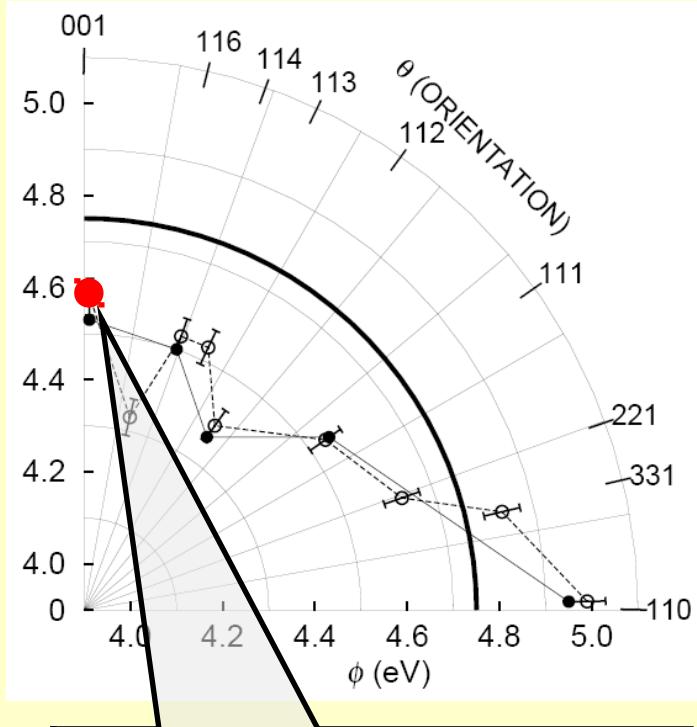
E, p_T conservation
PLUS
Barrier transmission, $T(p_z, p_{z0})$



Spatially-averaged
 $\Delta p_{T0} = 0.267 (m_0 \cdot \text{eV})^{1/2}$

Photoemission Simulation: Mo

– bcc crystal lattice



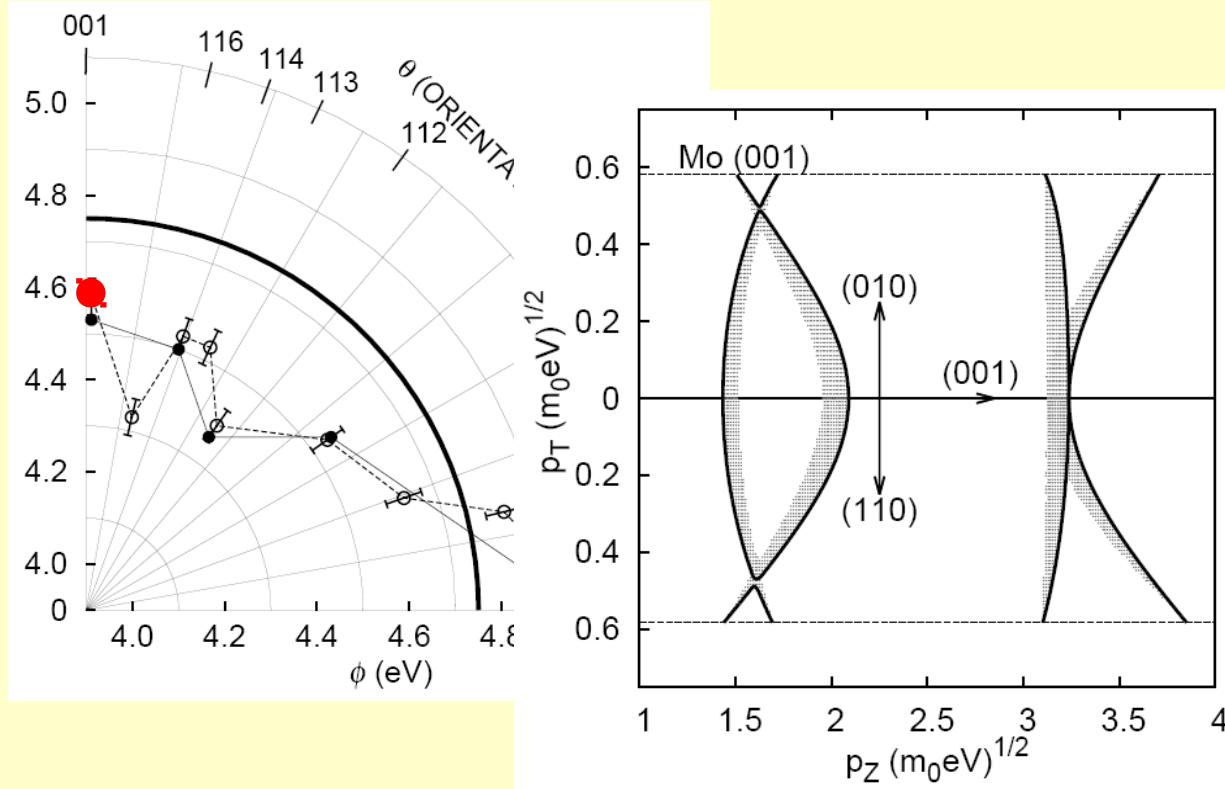
Lowest index face
with lowest $\phi_{(ijk)}$

$$\Delta E = \hbar\omega - \phi_{(001)} = 0.22\text{eV}$$

... $\pm 50\text{meV}$ error in $\phi_{(ijk)}$

Photoemission Simulation: Mo

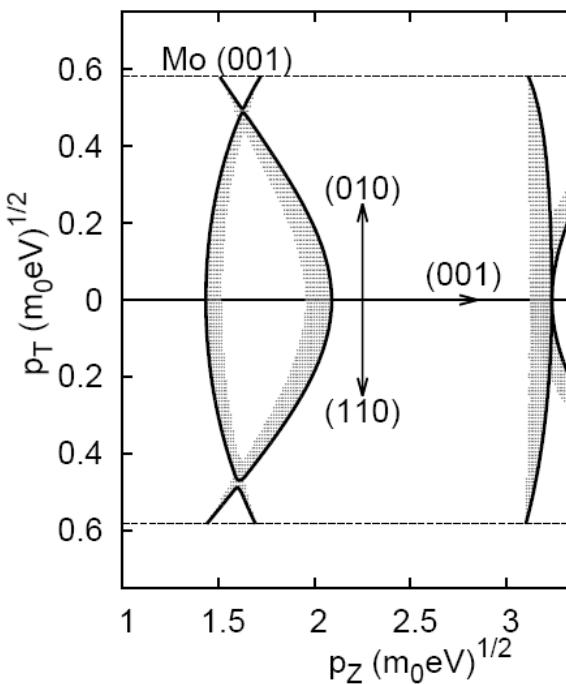
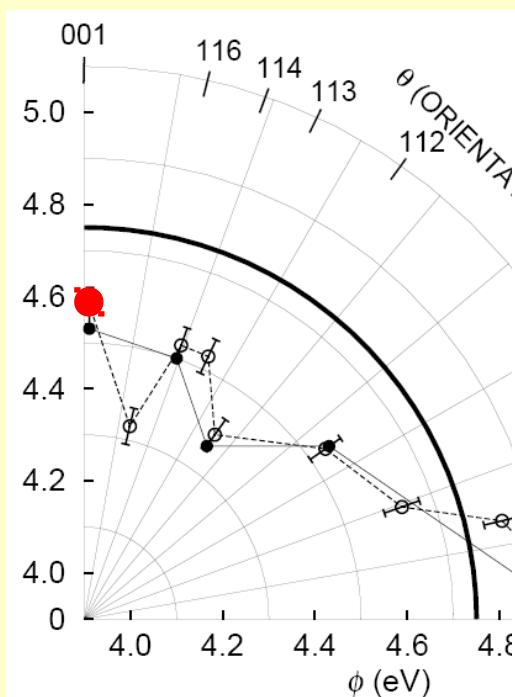
– bcc crystal lattice



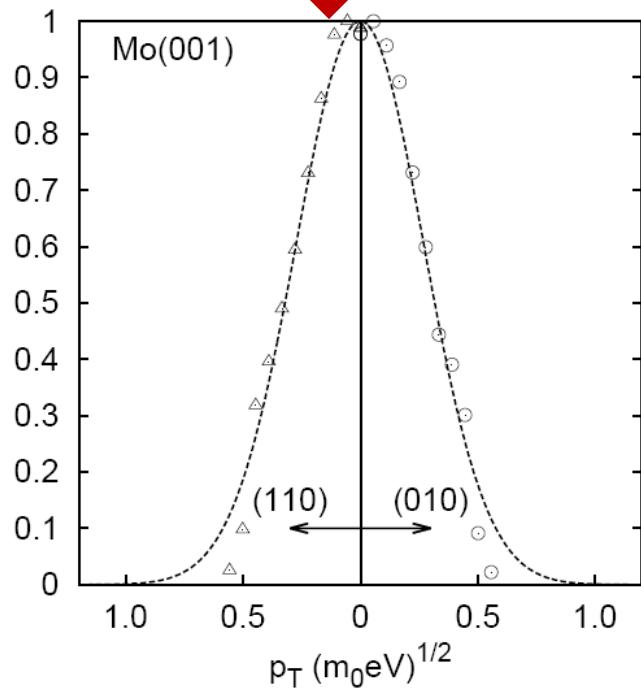
Both electron- and hole-like
states contribute to
photoemission

Photoemission Simulation: Mo

– bcc crystal lattice



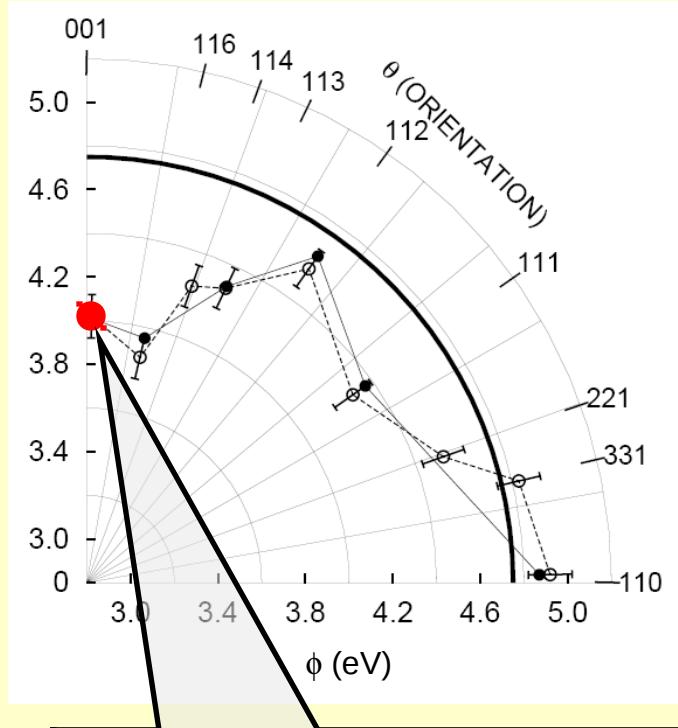
E, \mathbf{p}_T conservation
PLUS
Barrier transmission, $T(p_z, p_{z0})$



Spatially-averaged
 $\Delta p_{T0} = 0.219 (\text{m}_0 \cdot \text{eV})^{1/2}$

Photoemission Simulation: Nb

– bcc crystal lattice



Lowest index face
with lowest $\phi_{(ijk)}$

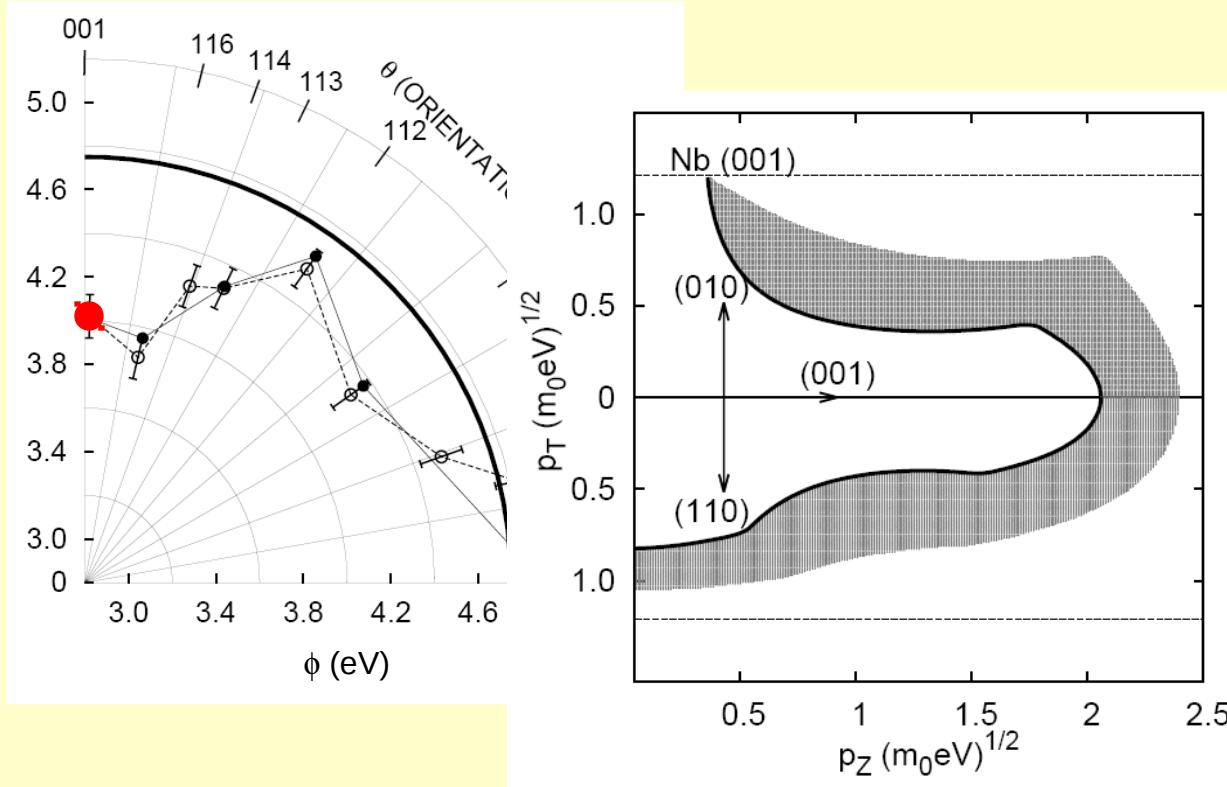
$$\Delta E = \hbar\omega - \phi_{(001)} = 0.73\text{eV}$$

... $\pm 50\text{meV}$ error in $\phi_{(ijk)}$

Photoemission Simulation: Nb

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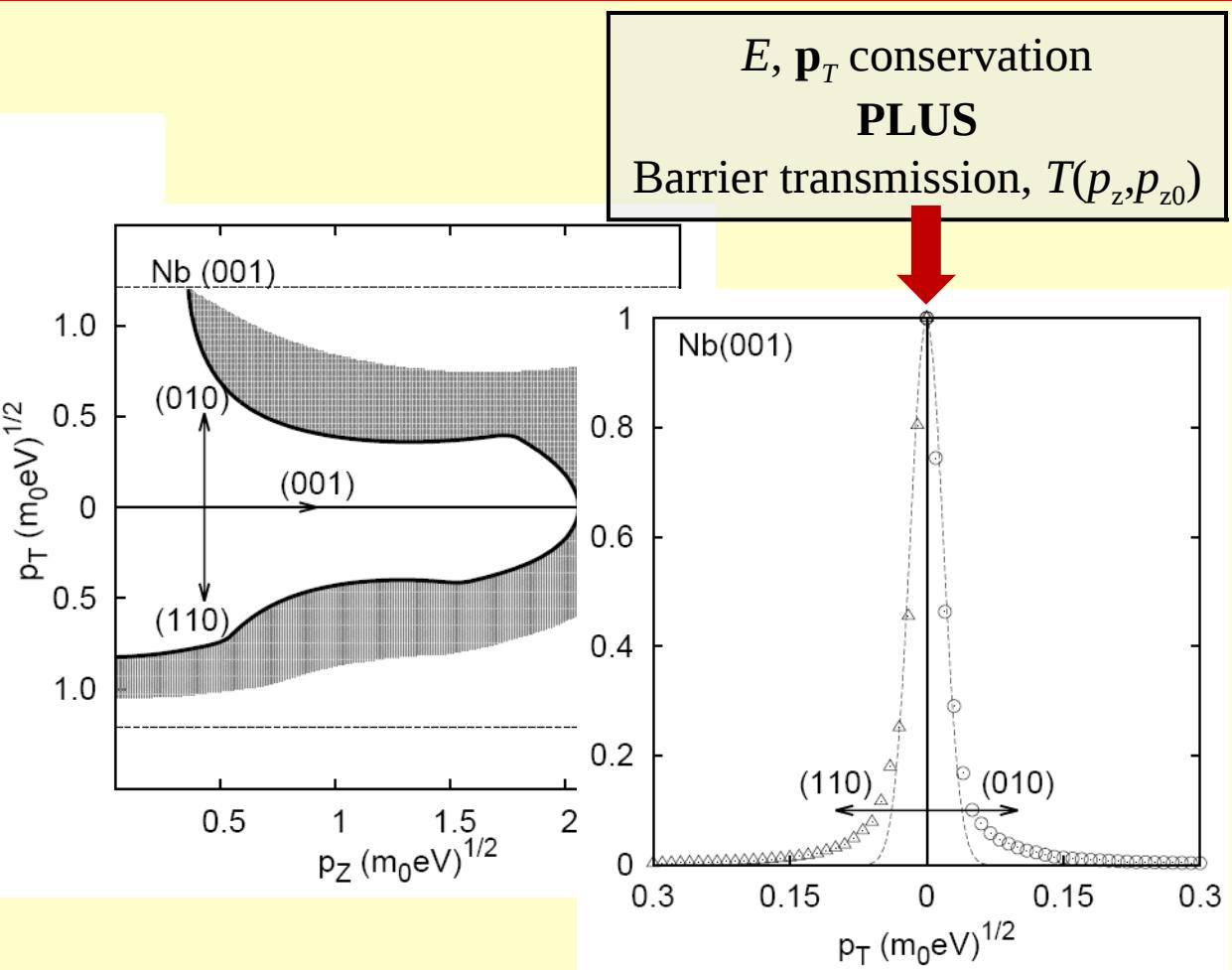
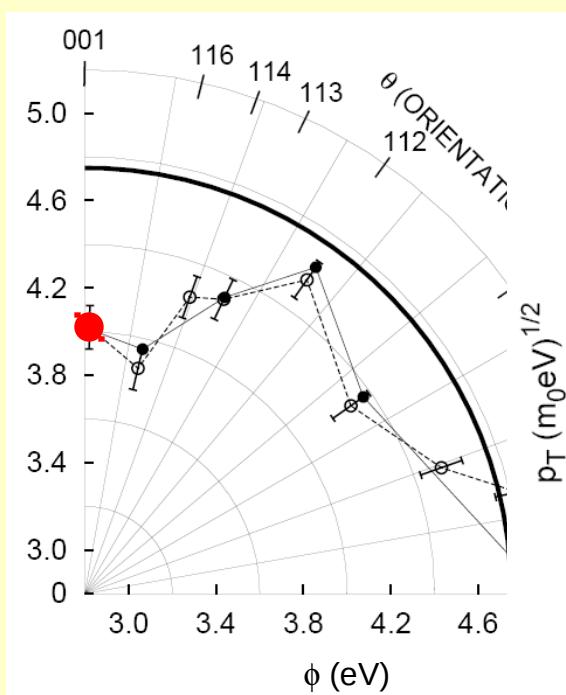
– bcc crystal lattice



Only hole-like states contribute
to photoemission

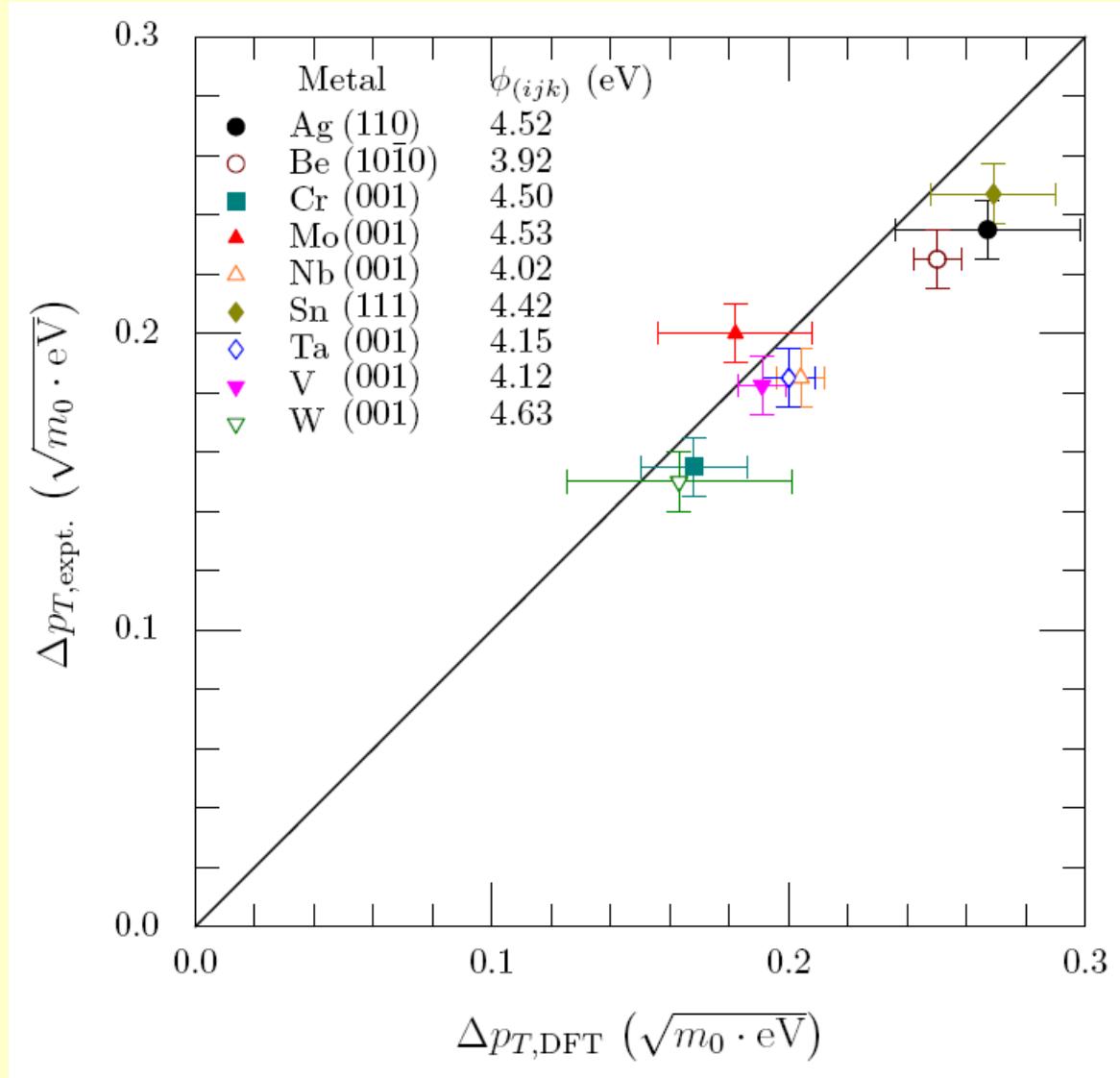
Photoemission Simulation: Nb

– bcc crystal lattice



Spatially-averaged
 $\Delta p_{T0} = 0.196 \text{ (m}_0\text{.eV)}^{1/2}$

Experiment vs. DFT Analysis

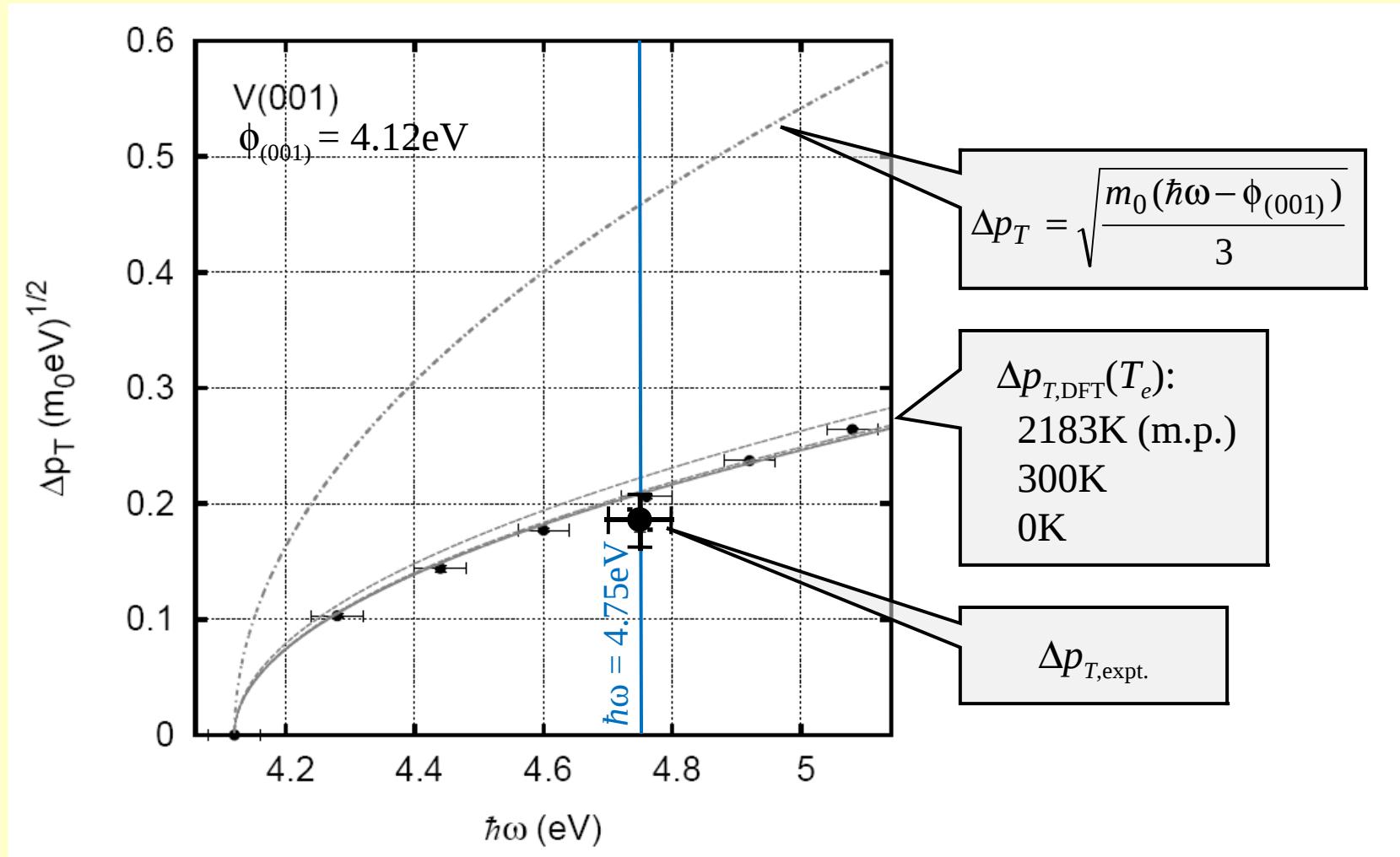


NOTE:

- Polycrystalline vs. single-crystal comparison
 - Other crystal faces with smaller $\Delta E = \hbar\omega - \phi_{(ijk)}$
 - contribute lower Δp_{T_0}
- DFT analysis at $T_e \rightarrow 0K$
Experiment at 300K
- Cu is missing ...
- Be is HCP
 \Rightarrow Anisotropic Δp_{T_0} ?

$\Delta p_T(T_e)$ for V(001) emission

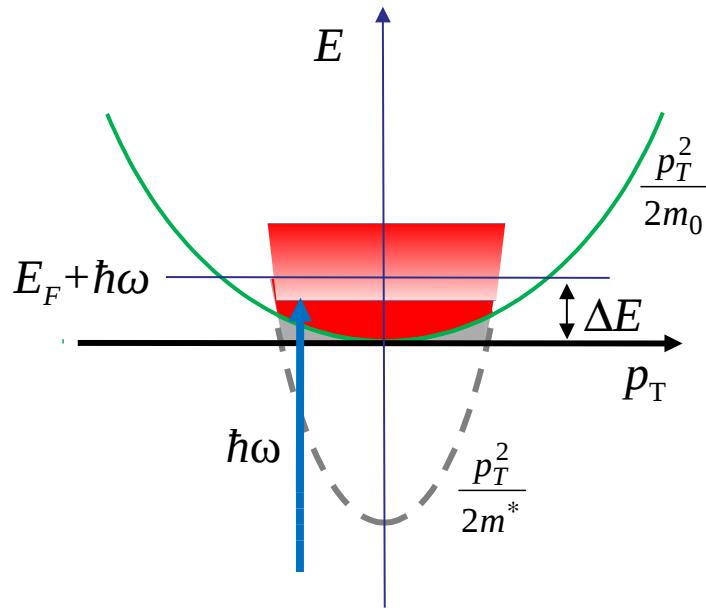
– DFT band structure with Fermi-Dirac distribution for electrons



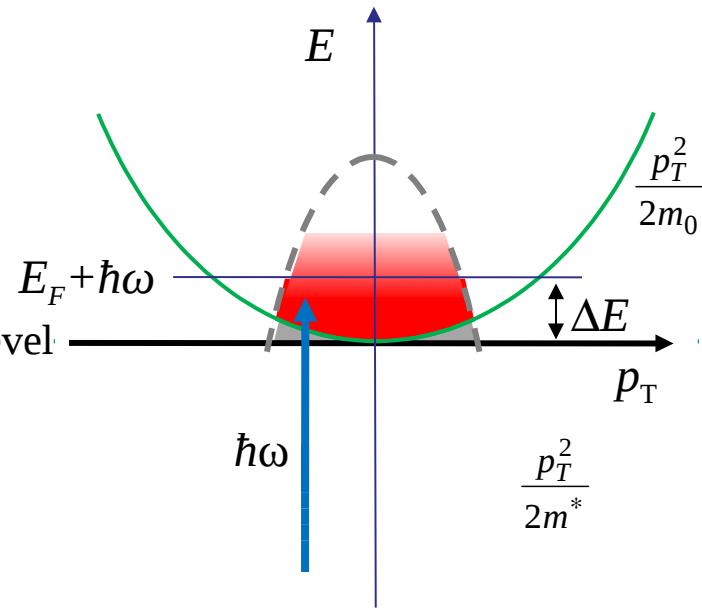
Electron-like vs. Hole-like States

– Δp_{T0} and its sensitivity to T_e

Electron-like ($m^* < m_0$)



Hole-like ($m^* < m_0$)

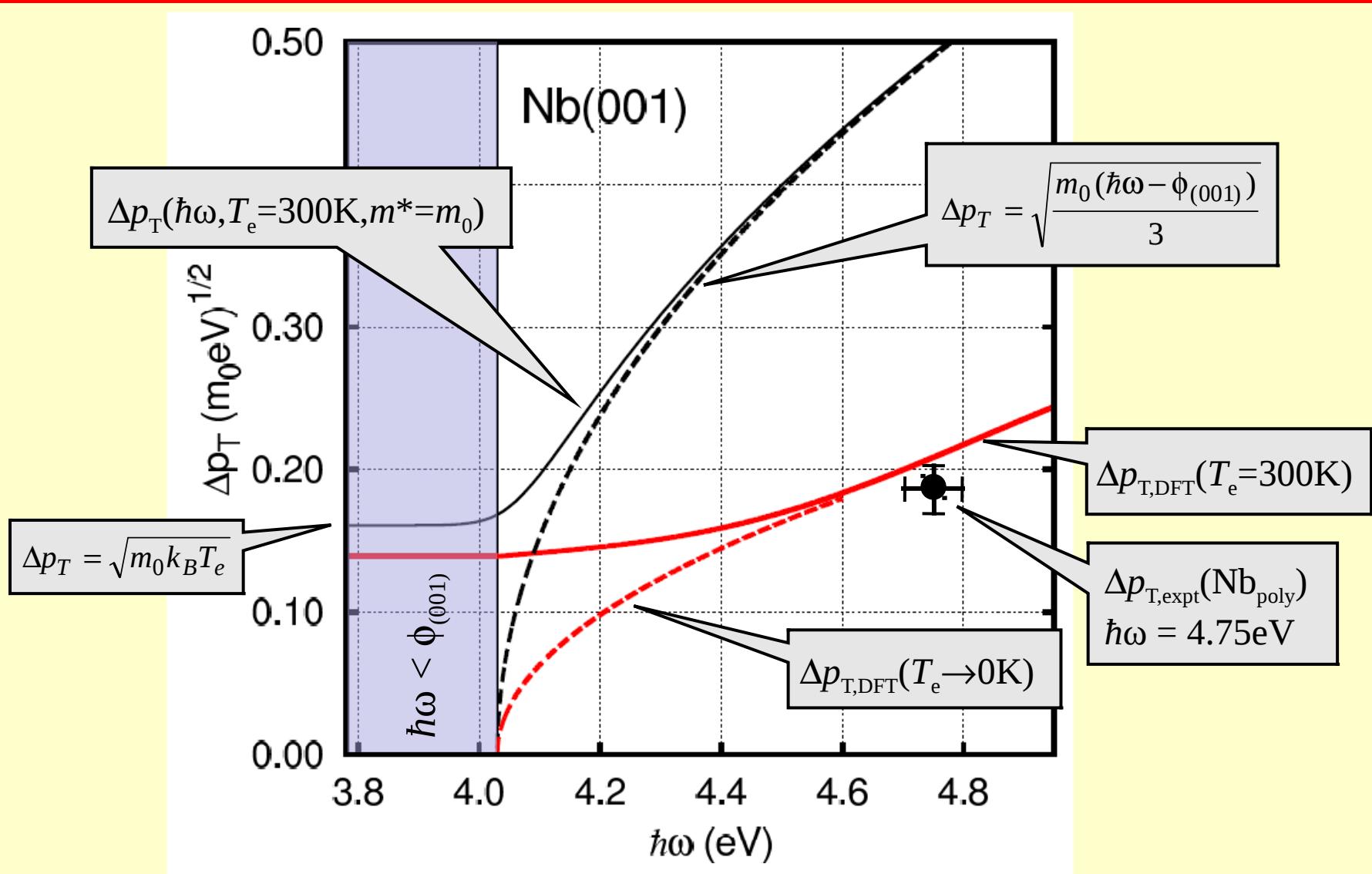


- Higher p_T electrons at high E
- More high p_T states occupied as T_e increases

- Lower p_T electrons at high E
- Less high p_T states occupied as T_e increases

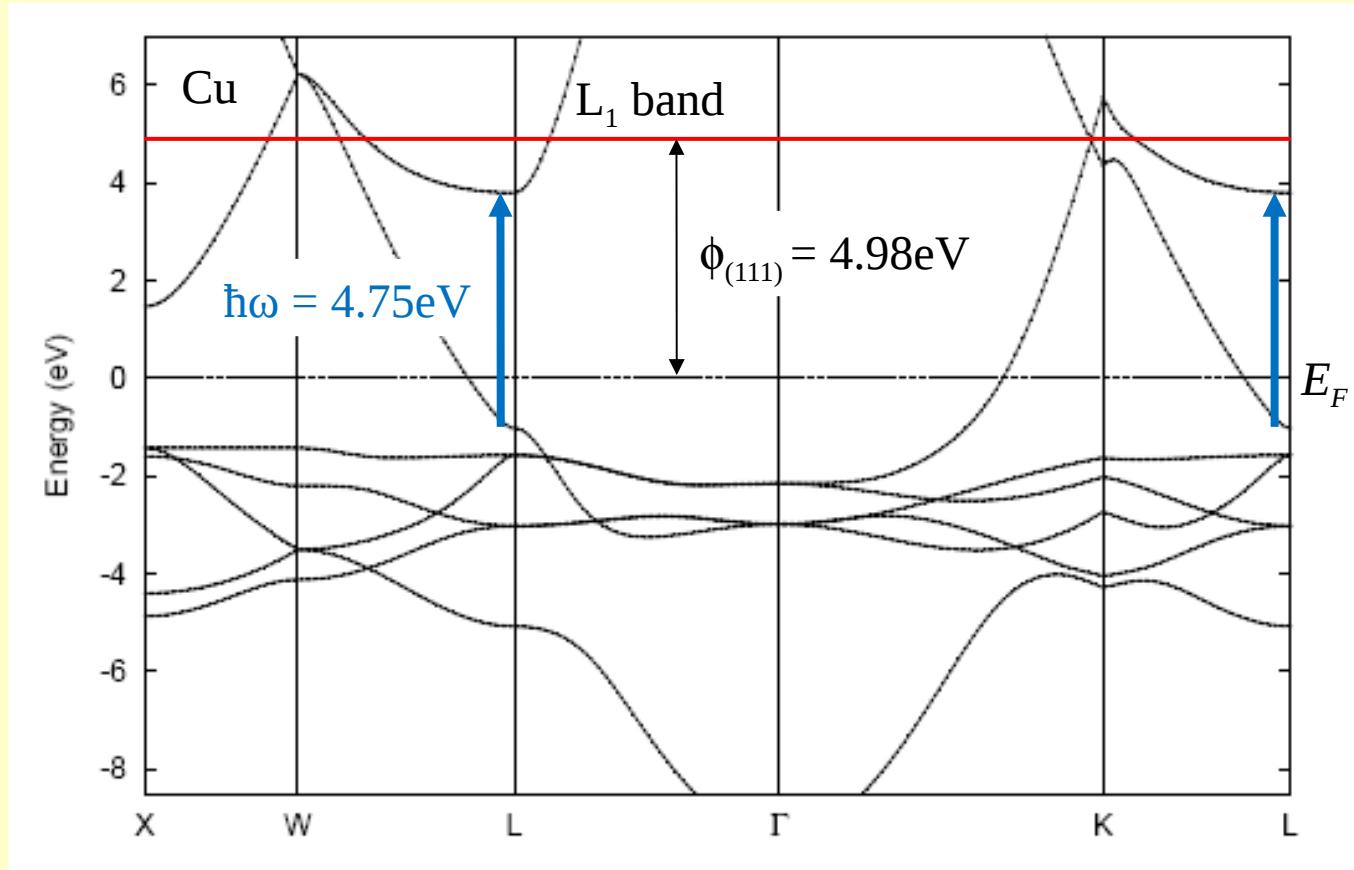
\therefore Low m^* hole-like states preferred

Temperature dependence: T_e



Copper Photocathodes

- Possible excited state emission process for Cu(111)



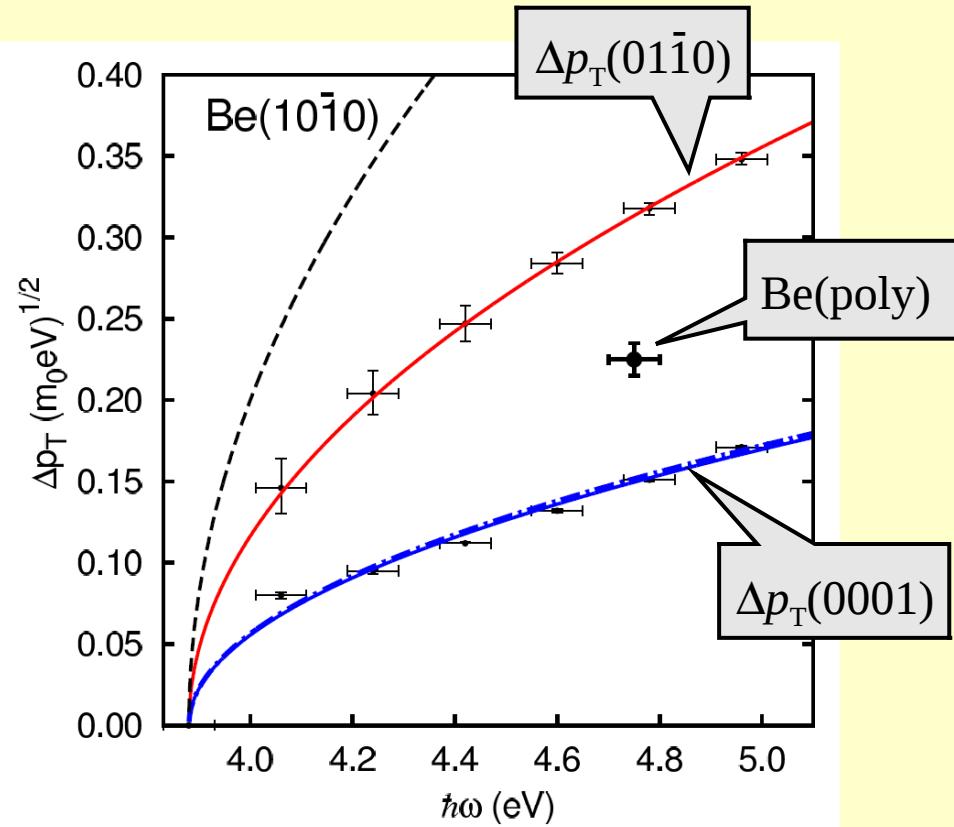
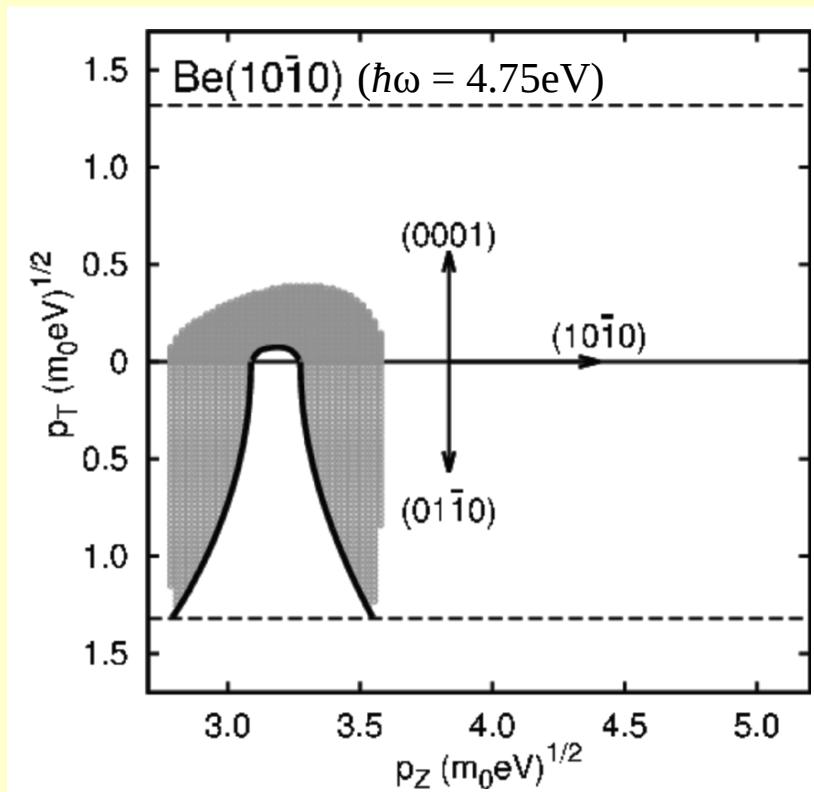
NOTE:

Could explain
higher than
expected QE for
polycrystalline Cu
photocathodes

HCP Metals: Be

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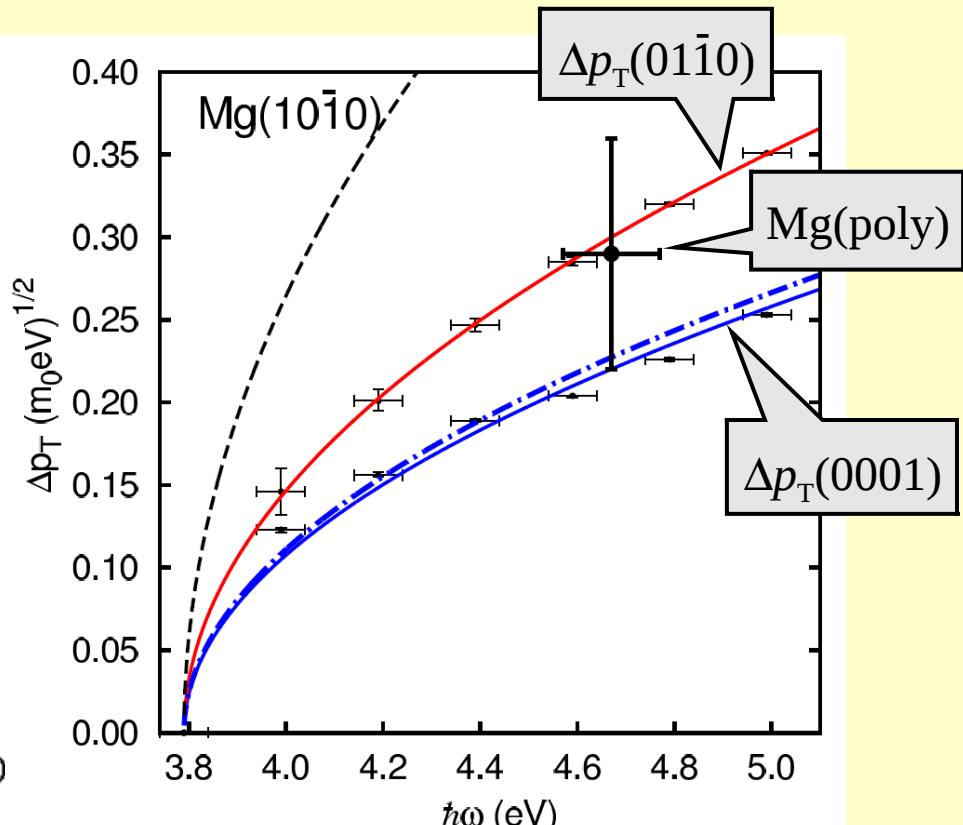
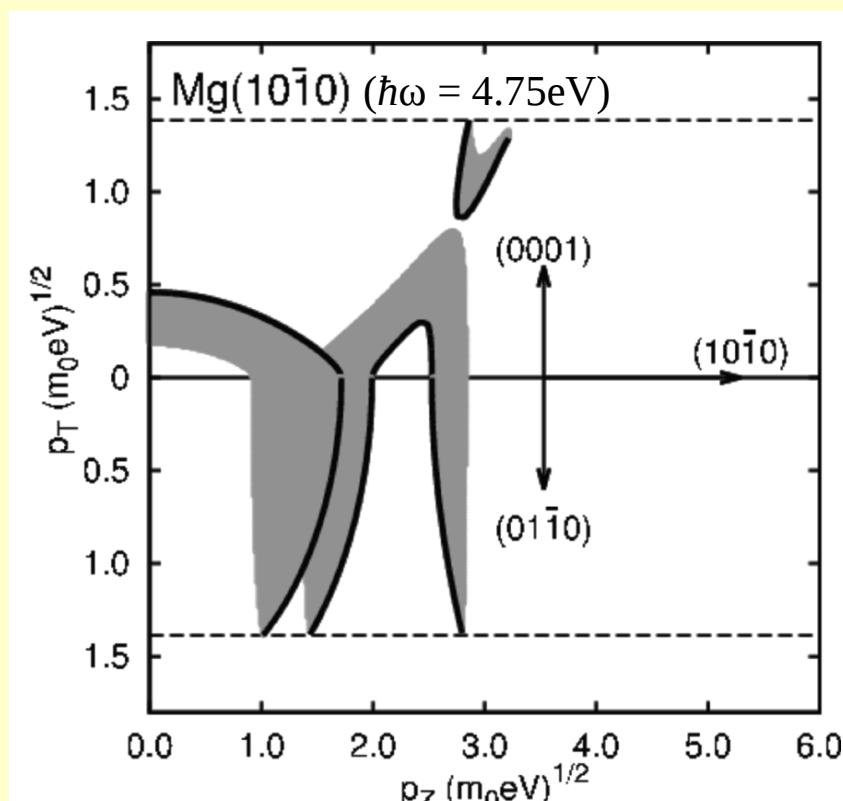
- Intrinsic electron state anisotropy in HCP crystal structure
- (1010)-face is most prevalent in polycrystalline HCP metals:



HCP Metals: Mg

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- Mg less anisotropic than Be



Summary

■ Photocathodes for UED

- **Single-crystals** for homogeneous electron beam generation ($\hbar\omega > \phi_{(ijk)}$)
⇒ Higher η_{PE} (?) and higher conductivity (σ and κ)
- Instantaneous response ⇒ **Virtual** excited state emission
- Emission from low m^* states: $p_F > p_{T,\max} \Rightarrow$ Lower Δp_{T0}
- ‘Hole-like’ emission states are preferred:
Even lower Δp_{T0} and less sensitive to T_e (e.g., laser heating)
- Robust (e.g., high m.p.) and chemically inert

■ Future work

- Direct comparison with theory: Single-crystal photocathodes
- Crystalline compounds: Mo_xNb_{1-x} , semiconductors, A_3B (e.g., Nb_3Sb), ...
- Search for ***ultra-low*** Δp_{T0} solid-state photocathodes:
 Δp_{T0} approaching cold atom electron sources ⇐ TID issues?

Thank you!

GaSb band structure

– Vacuum level at $\phi_{eff} = 4.84\text{eV}$ above bulk VB maximum

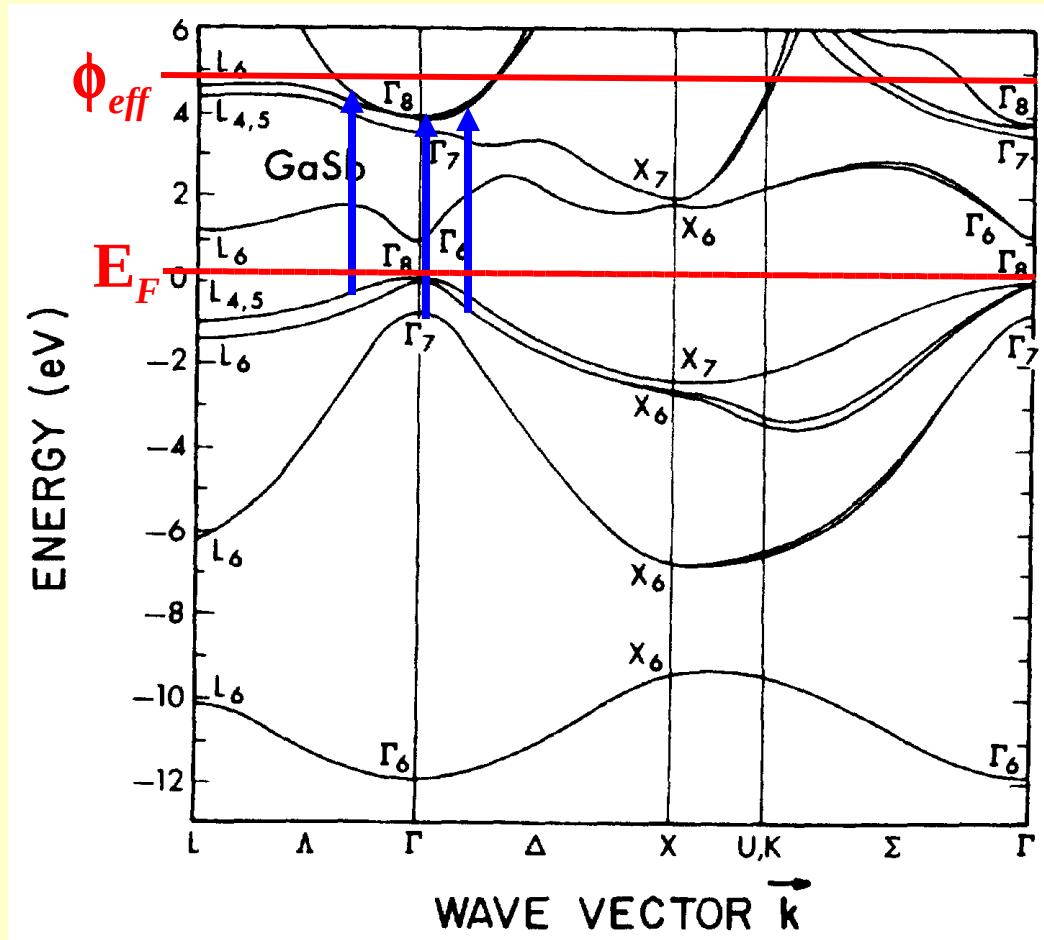
- Strong absorption at 261nm:

$$\alpha = 1.44 \times 10^6 \text{cm}^{-1}$$

$$\Rightarrow \alpha^{-1} \approx 7\text{nm}$$

... ‘metal-like’

- Γ -valley transitions from VB (HH, LH, and SO bands) to upper Γ_8 conduction band

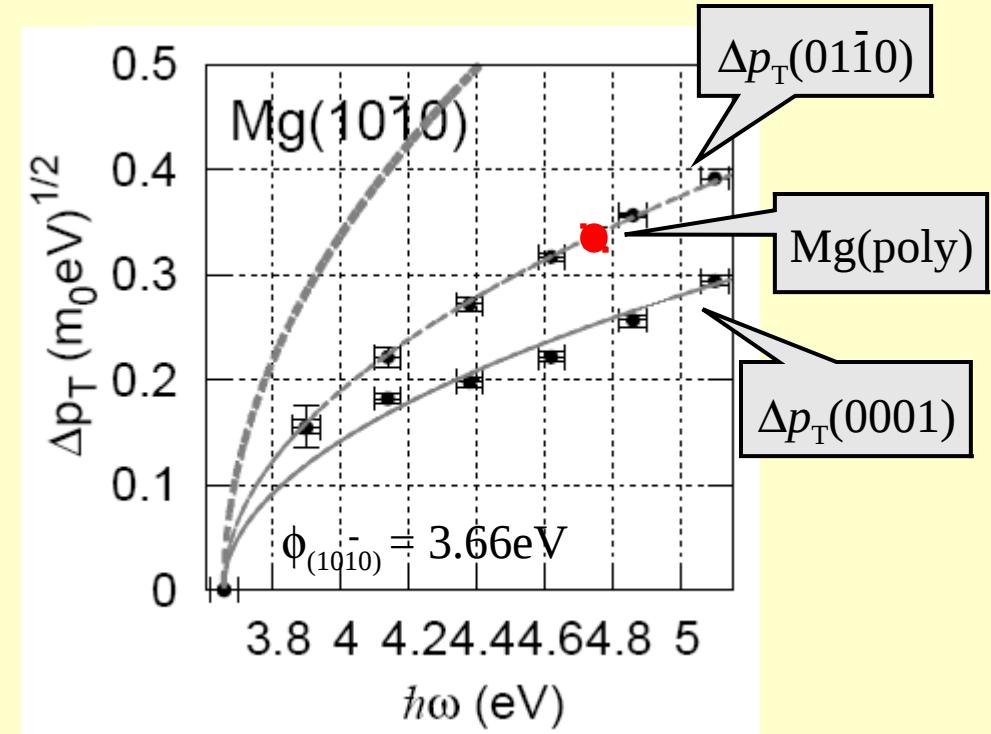
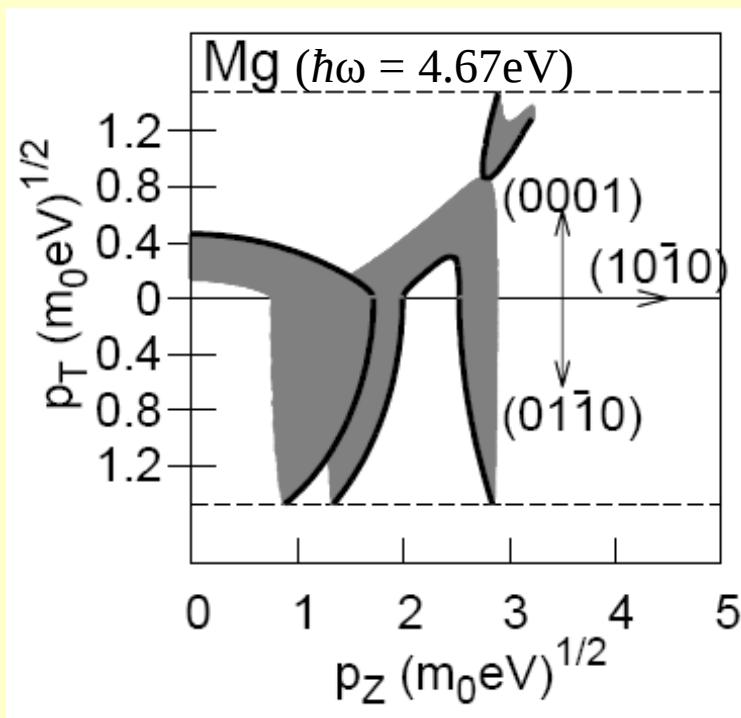


Finally ...

Calculating $\Delta p_T(ijk)$ for *all* elemental metals

– Results available on-line at <http://people.uic.edu/~tli27/Database.html>.

E.g., hcp Mg(1010) face emission:



Summary

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